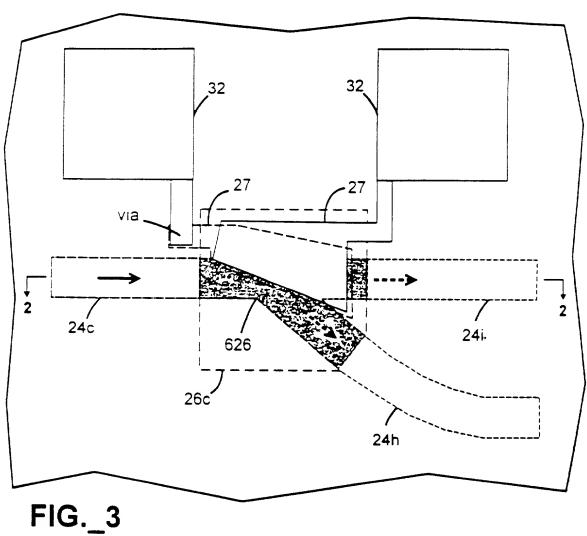


FIG._2



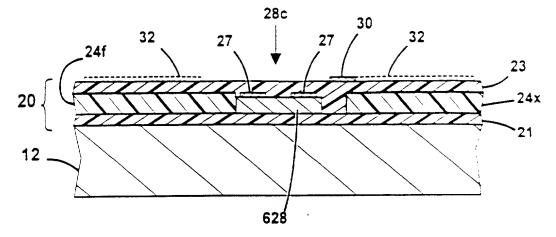


FIG._4-1

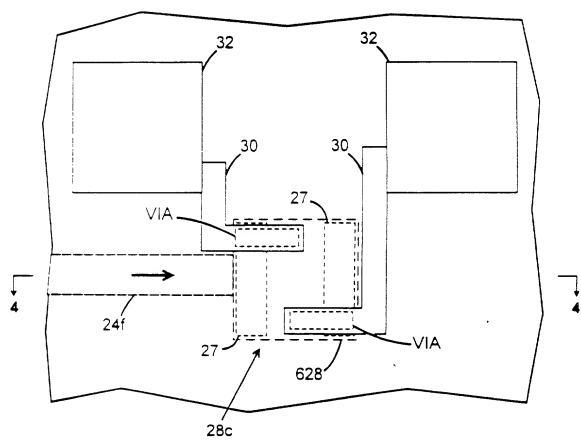
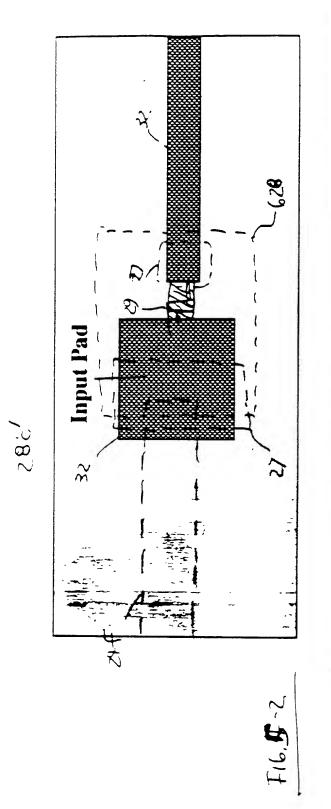
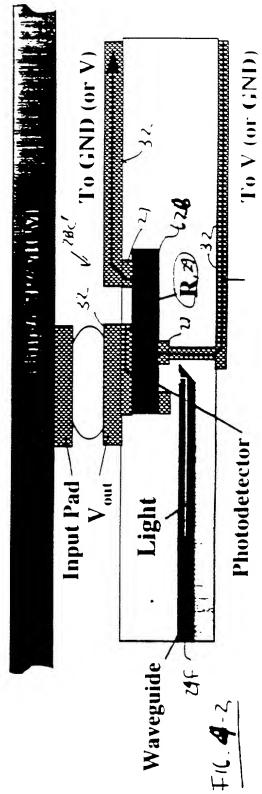
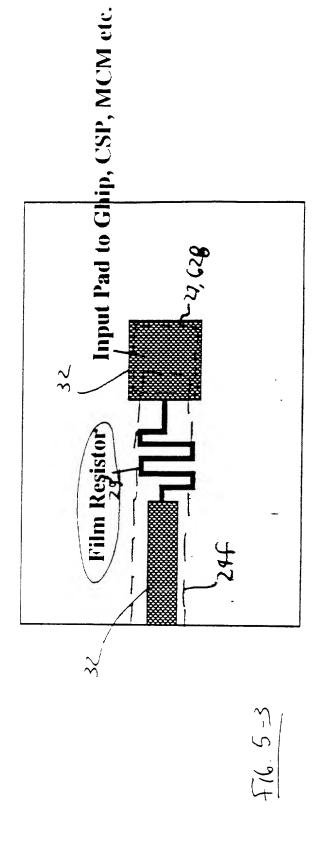
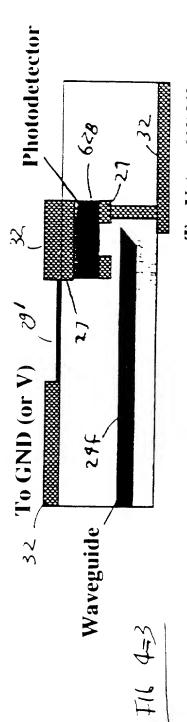


FIG._5-1

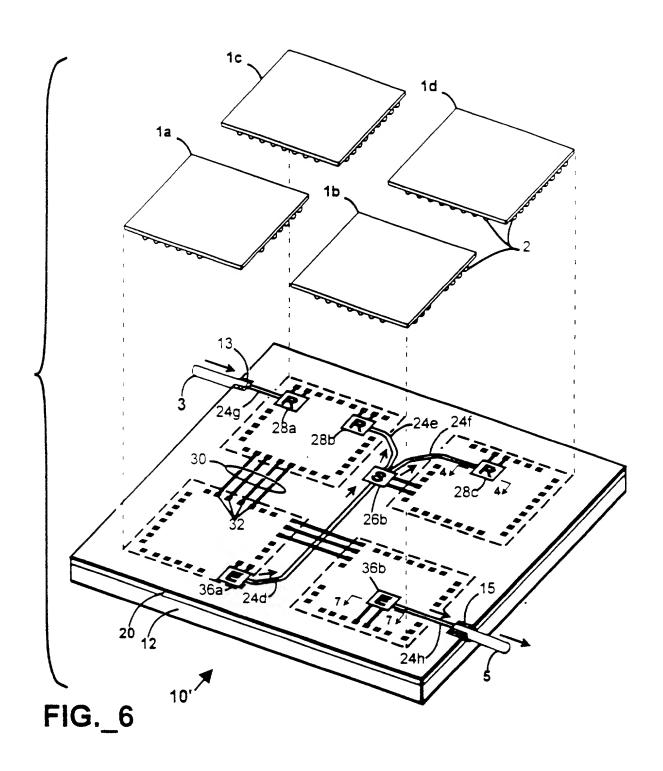








To V (or GRND)



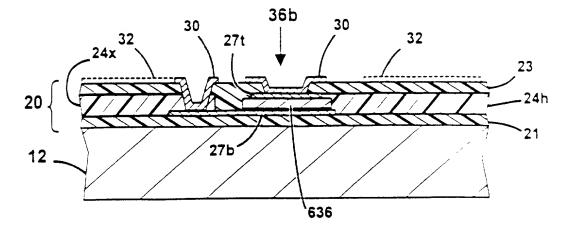
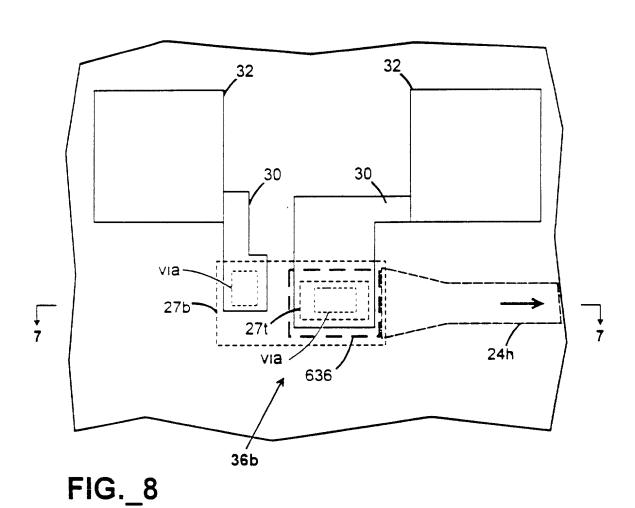
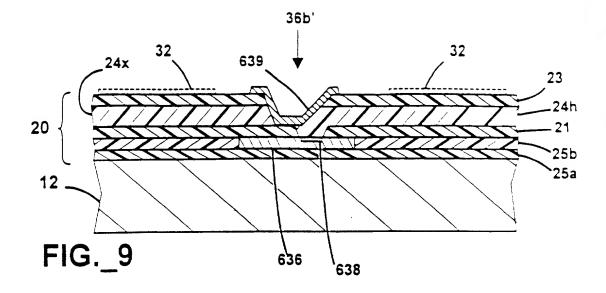


FIG._7





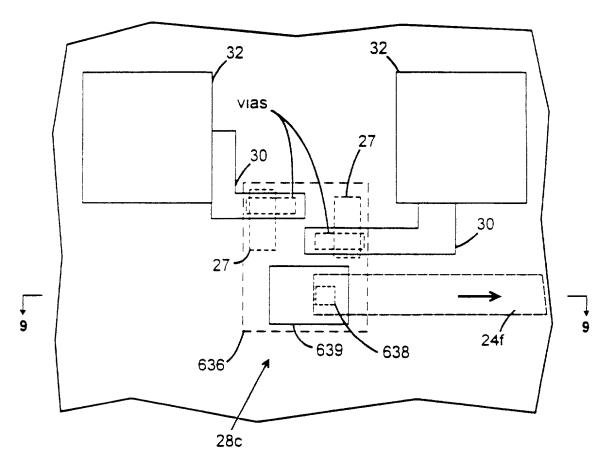
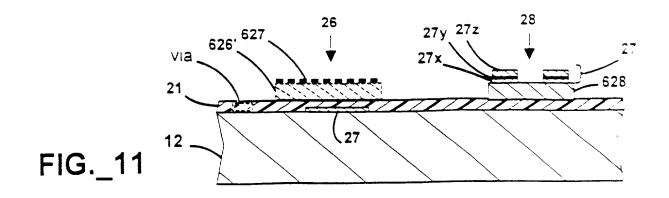
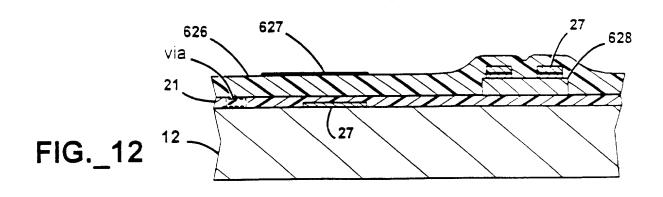
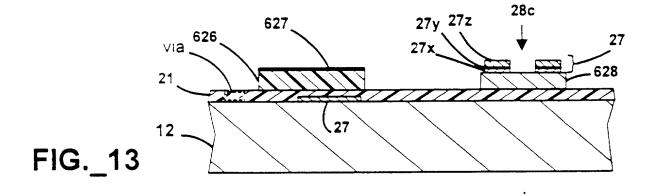
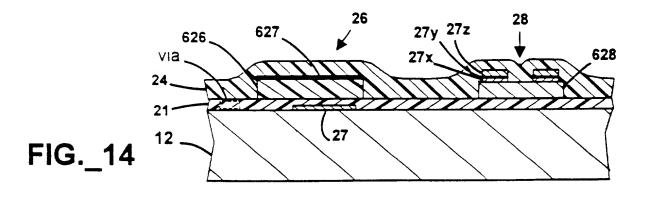


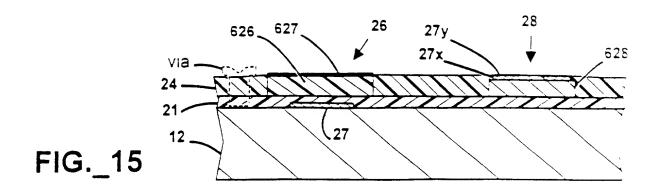
FIG._10

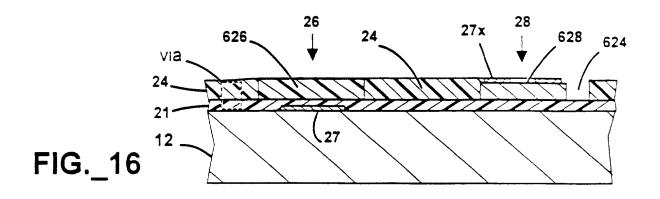


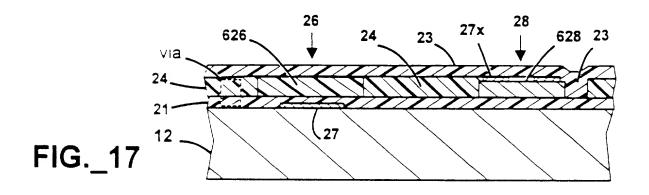


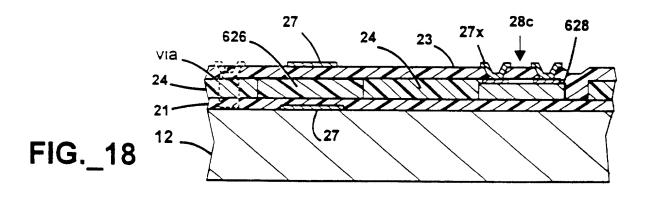












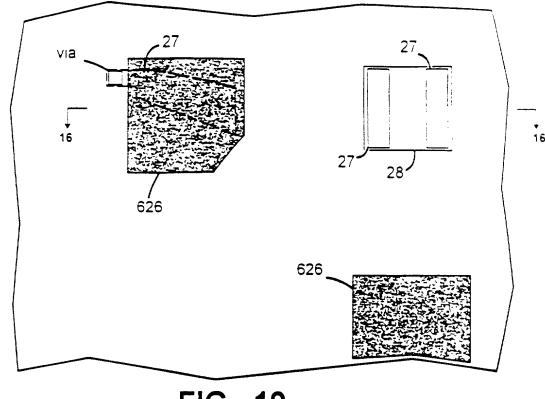


FIG._19

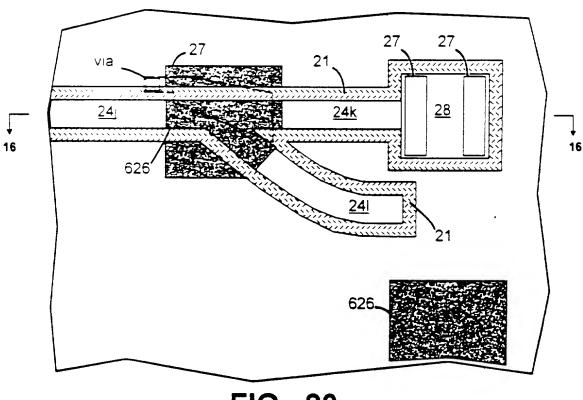


FIG._20

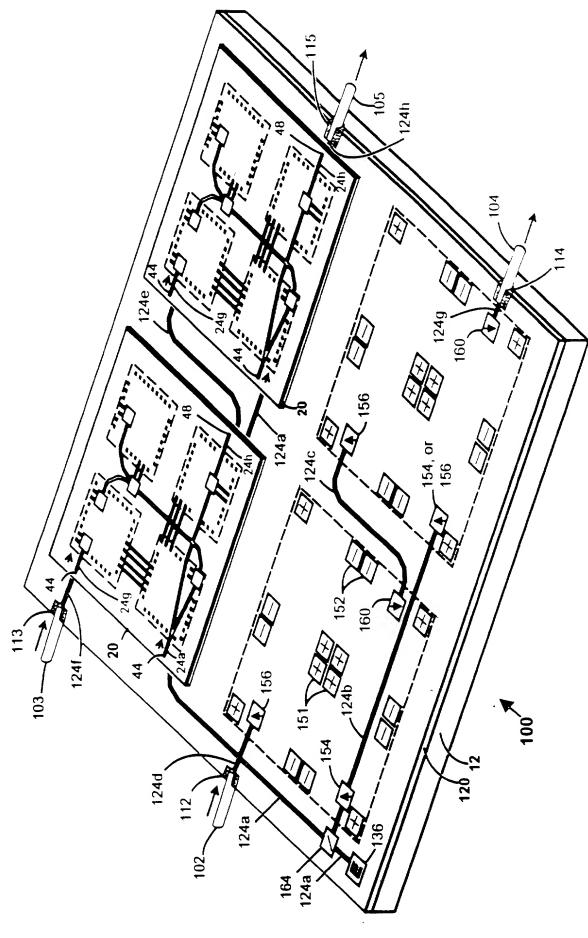


FIG. 2

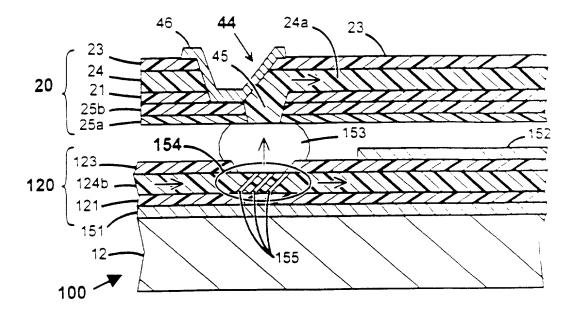


FIG._22

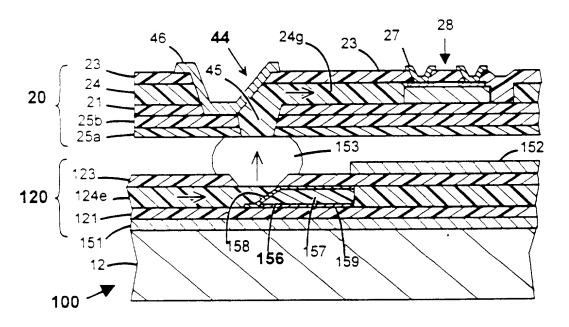


FIG._23

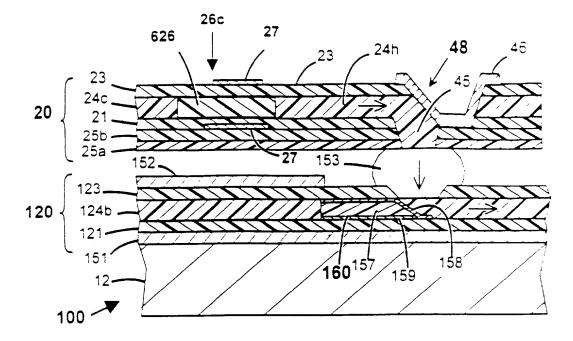
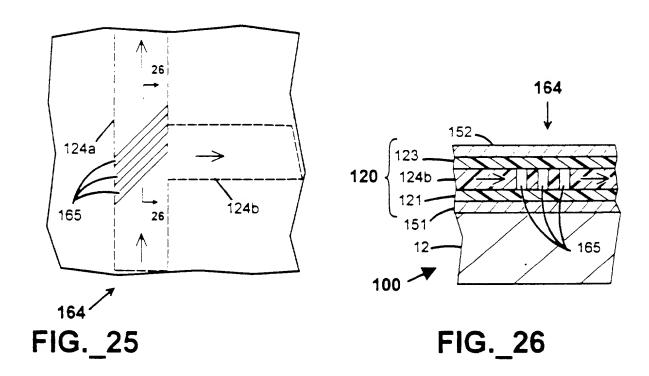
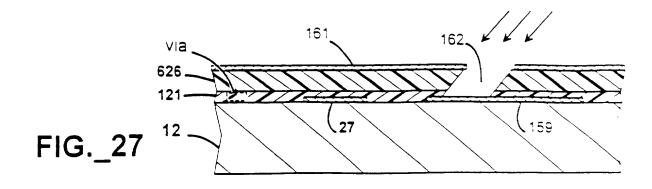
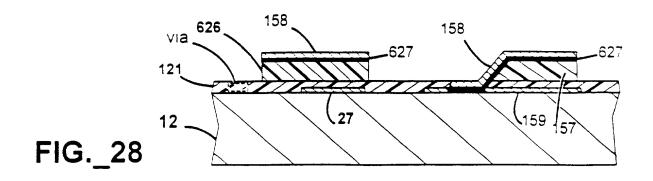
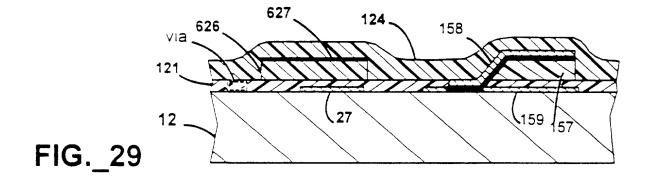


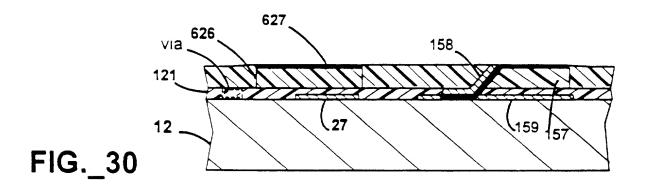
FIG._24

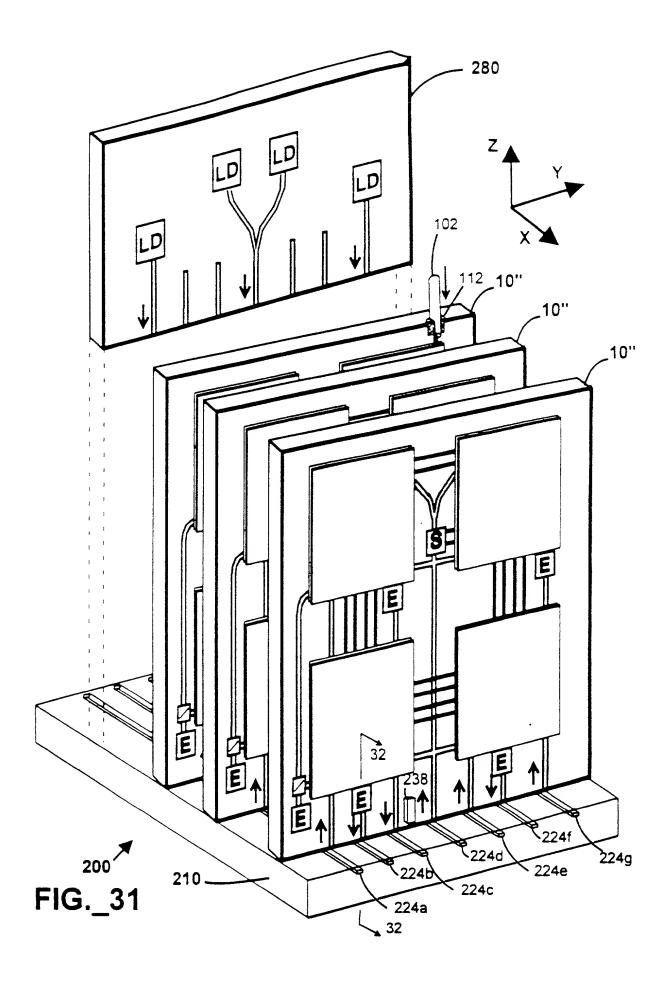


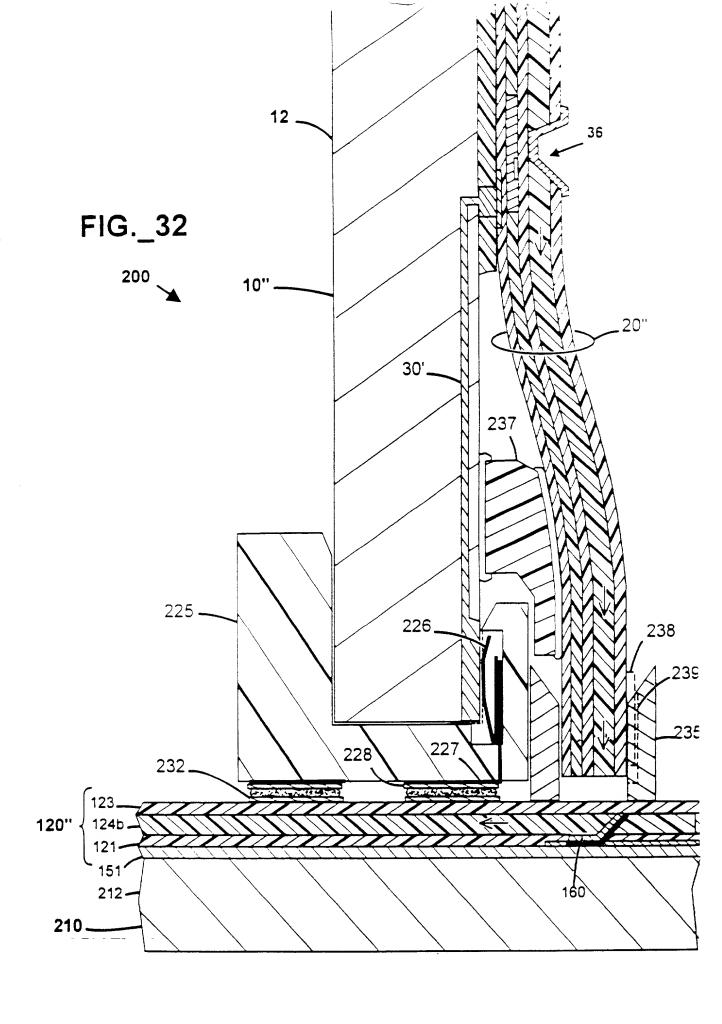


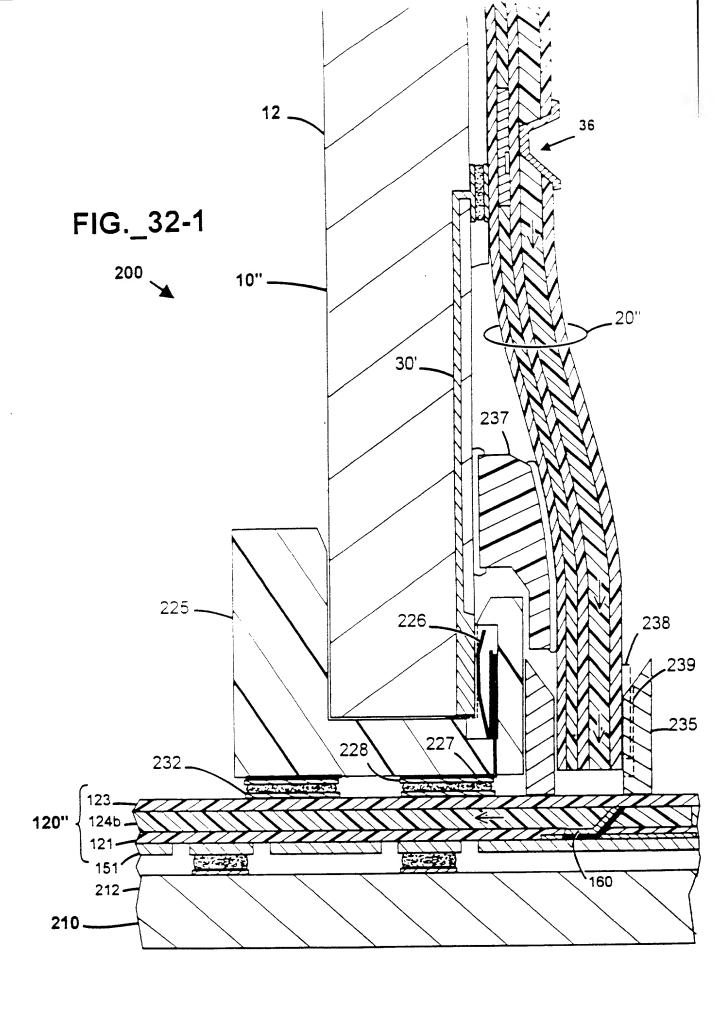


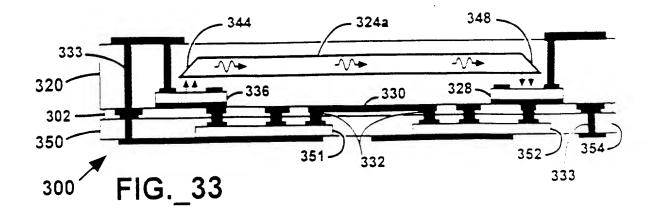












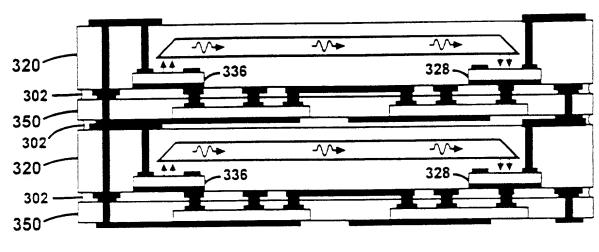
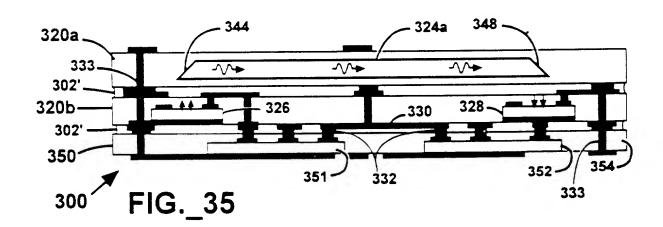


FIG._34



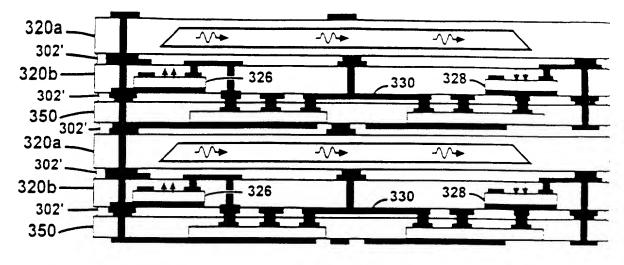
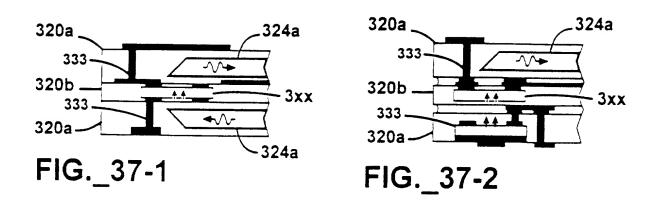
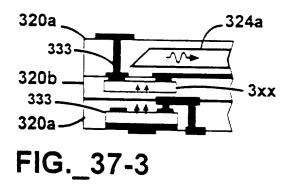


FIG._36





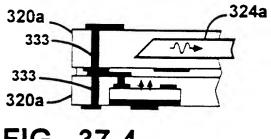


FIG._37-4

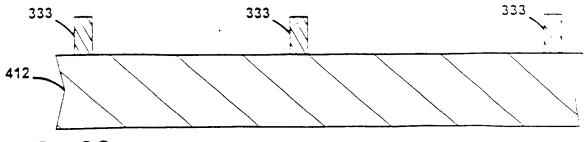


FIG._38

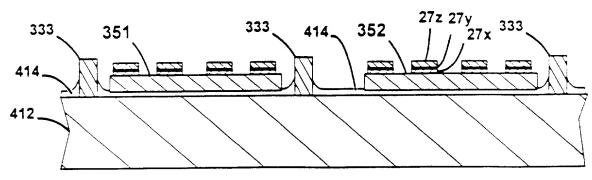


FIG._39

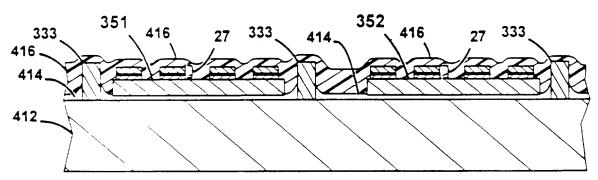


FIG._40

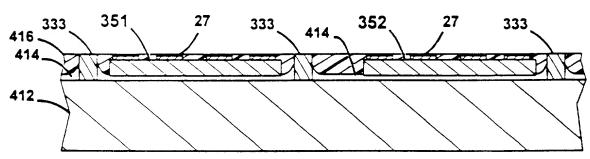


FIG._41

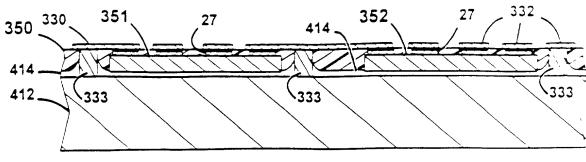


FIG._42

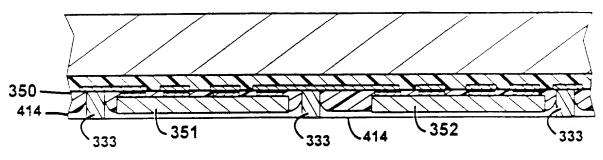


FIG._43

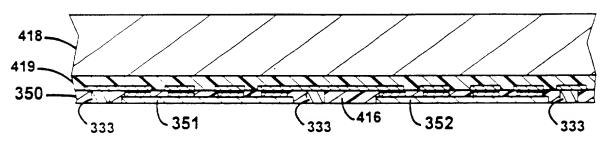


FIG._44

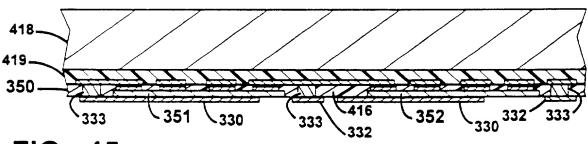
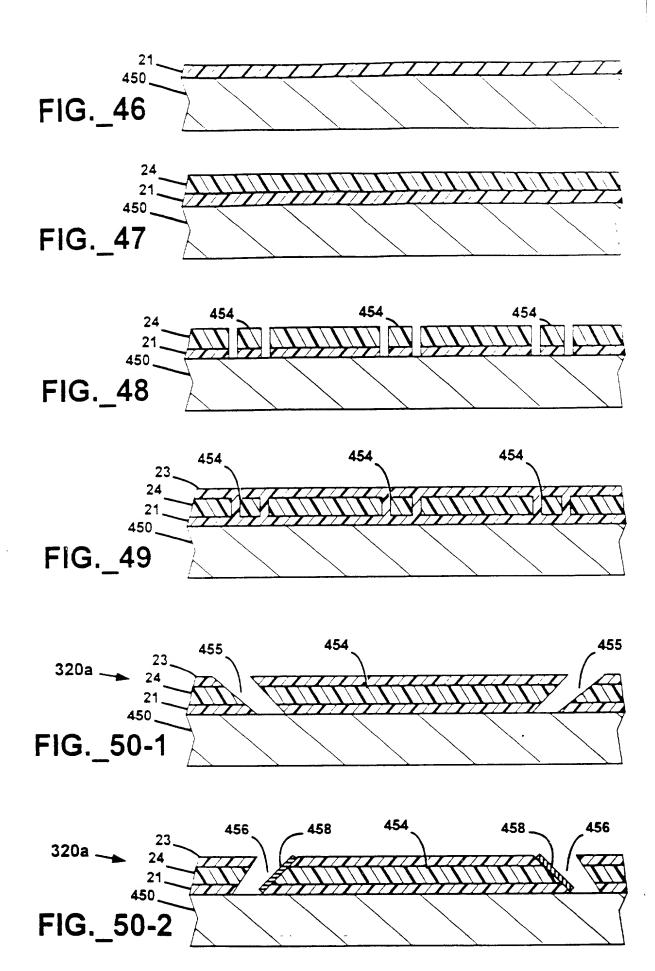
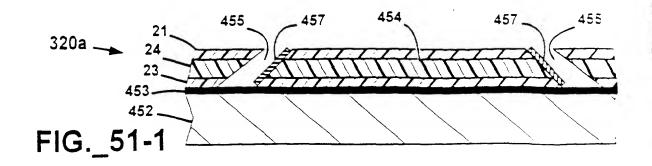
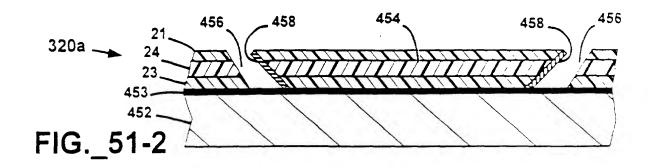
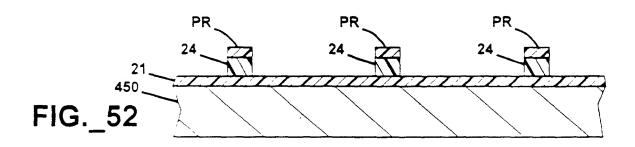


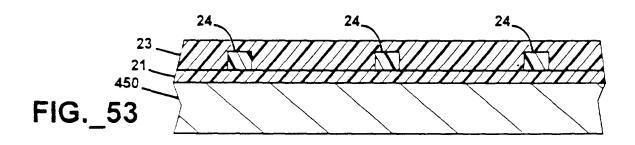
FIG._45

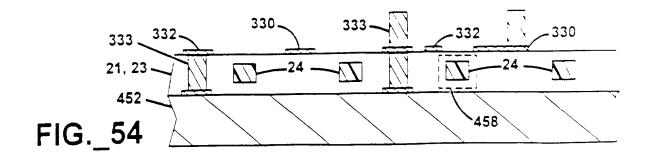


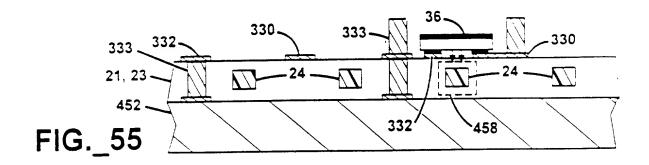


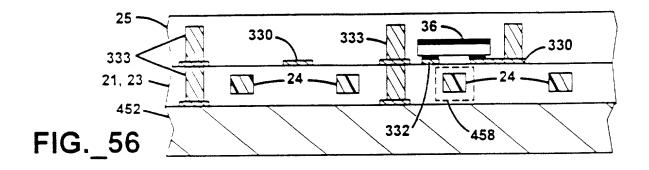


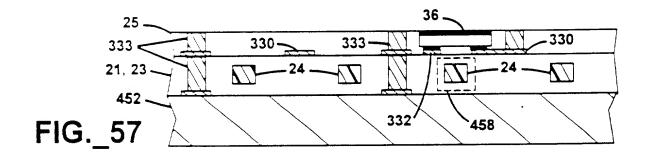


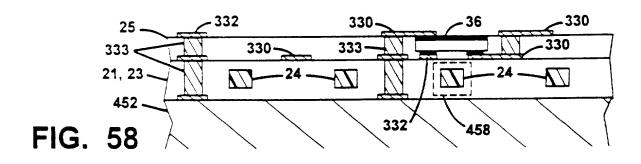


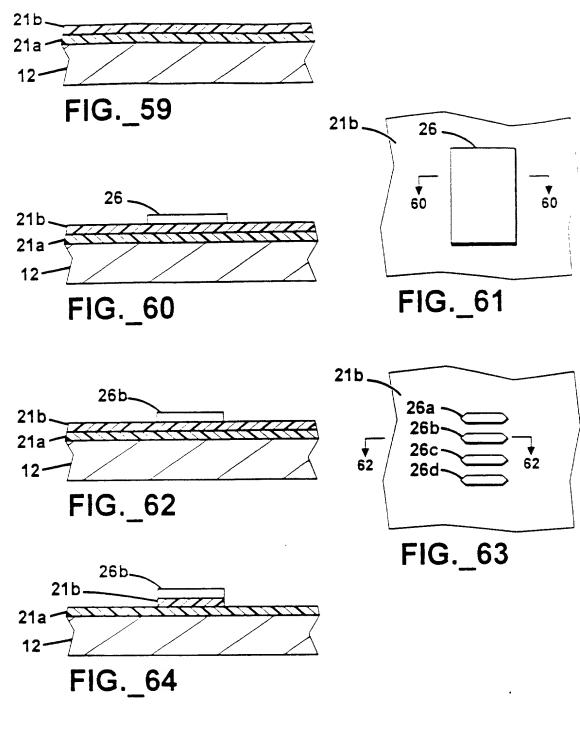


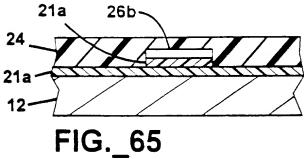


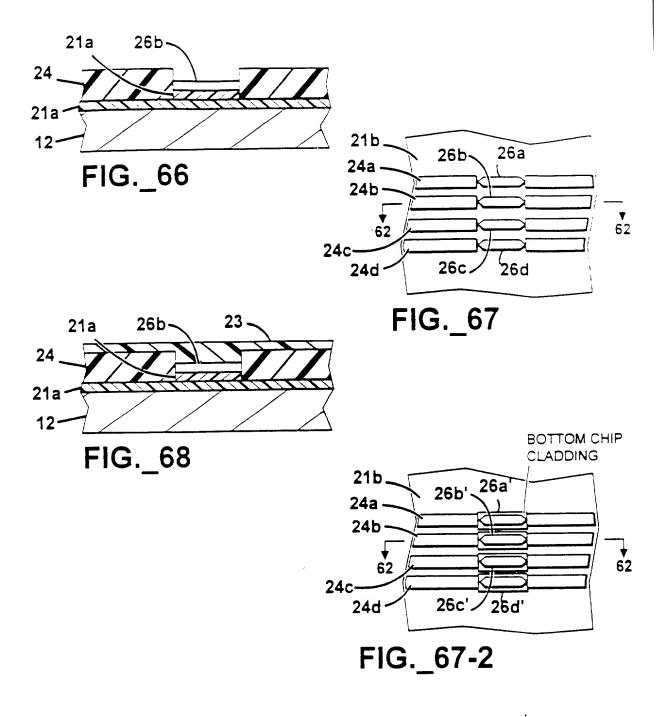


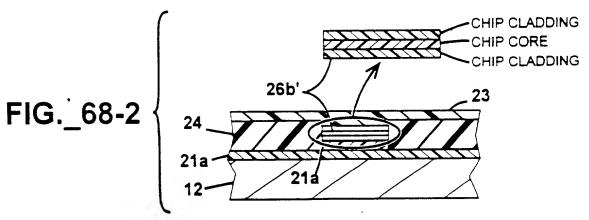


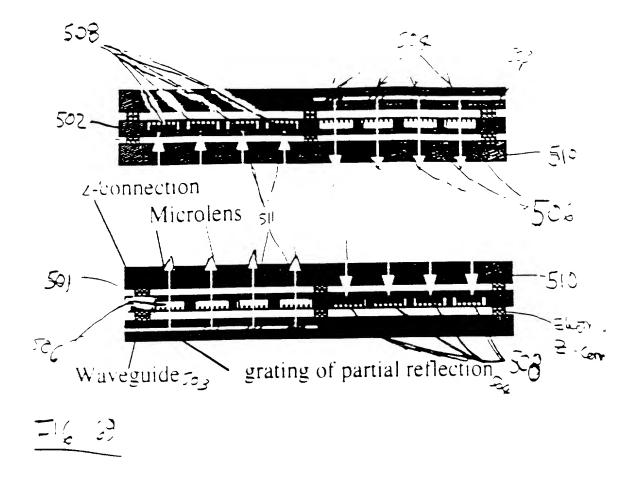


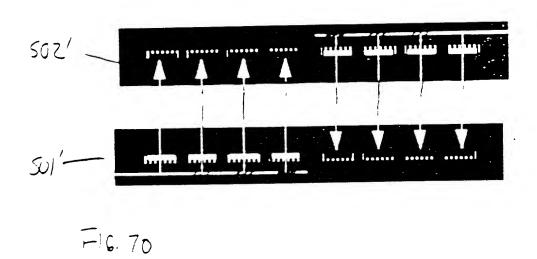


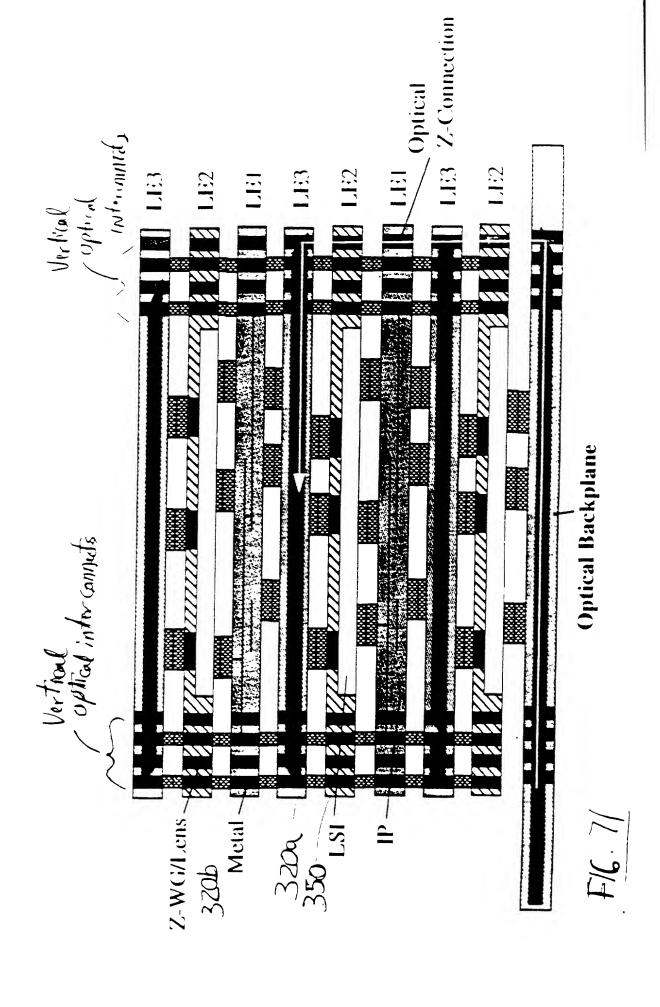


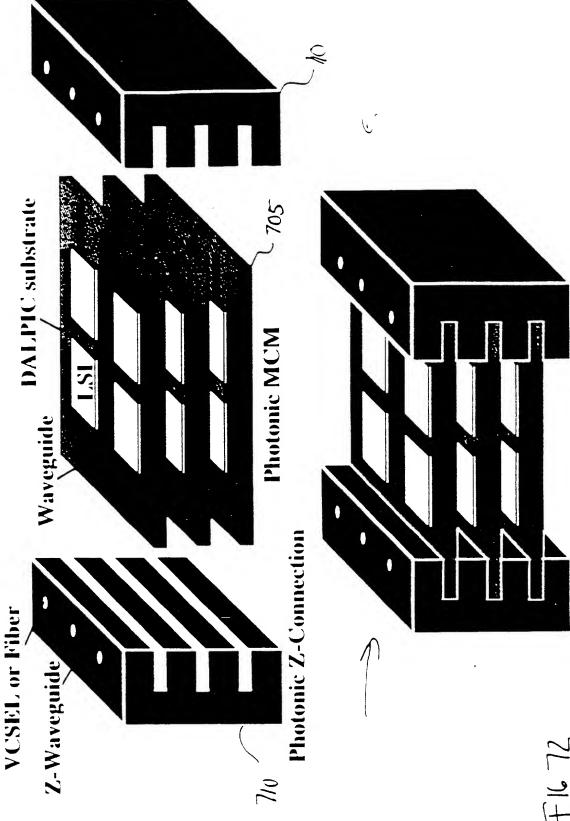


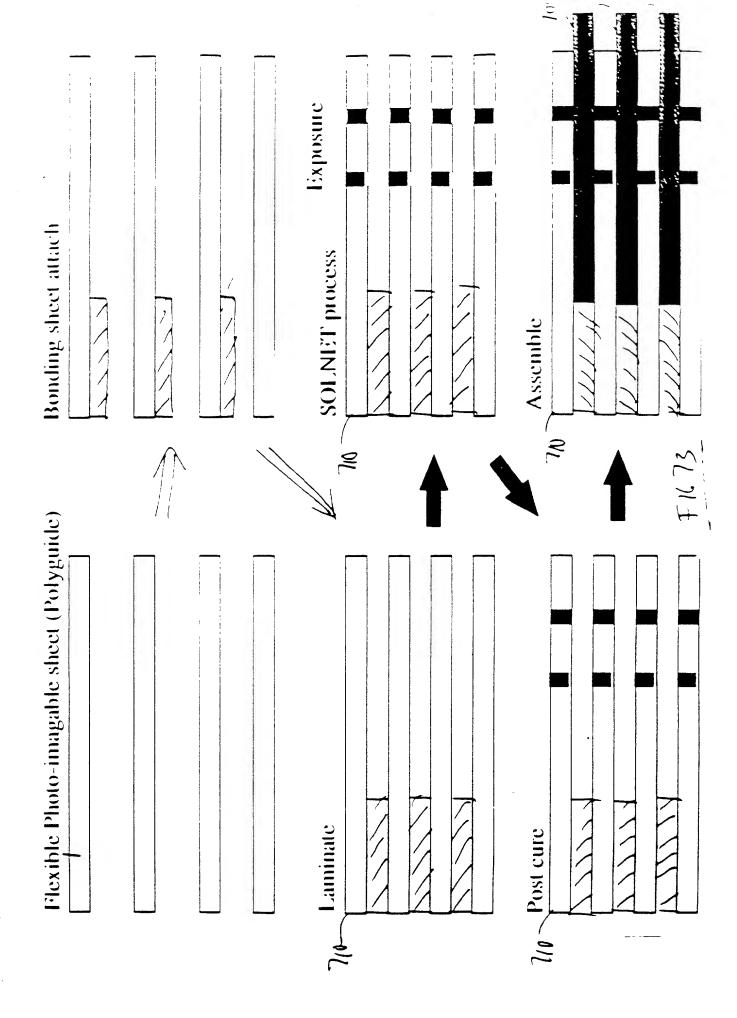












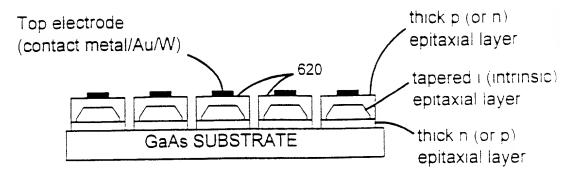
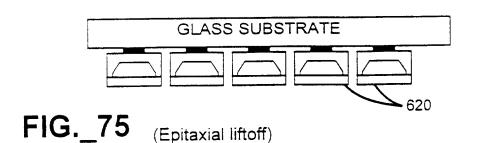


FIG._74 (Epitaxial growth and patterning)



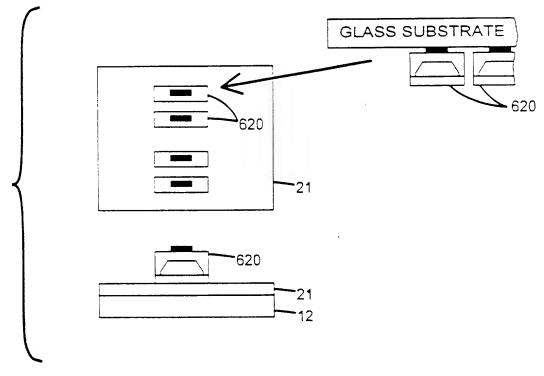
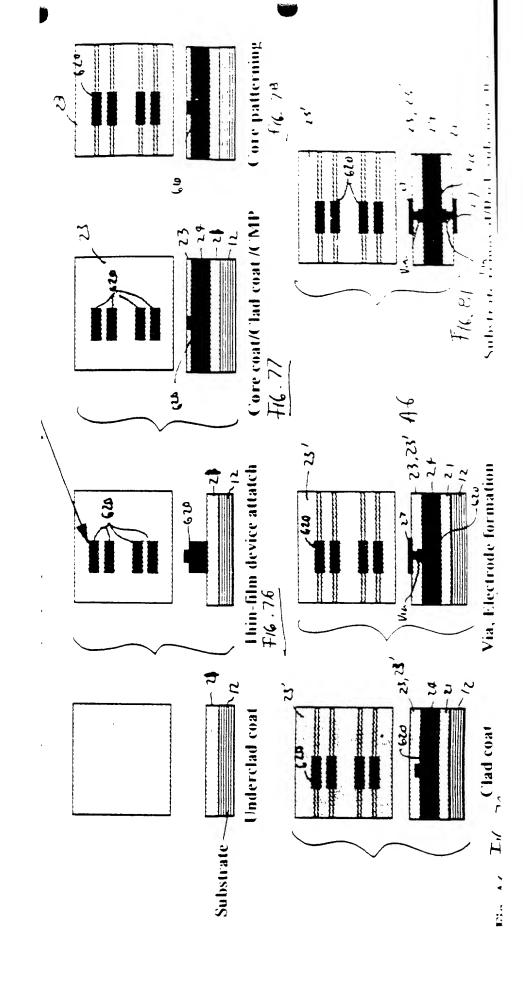
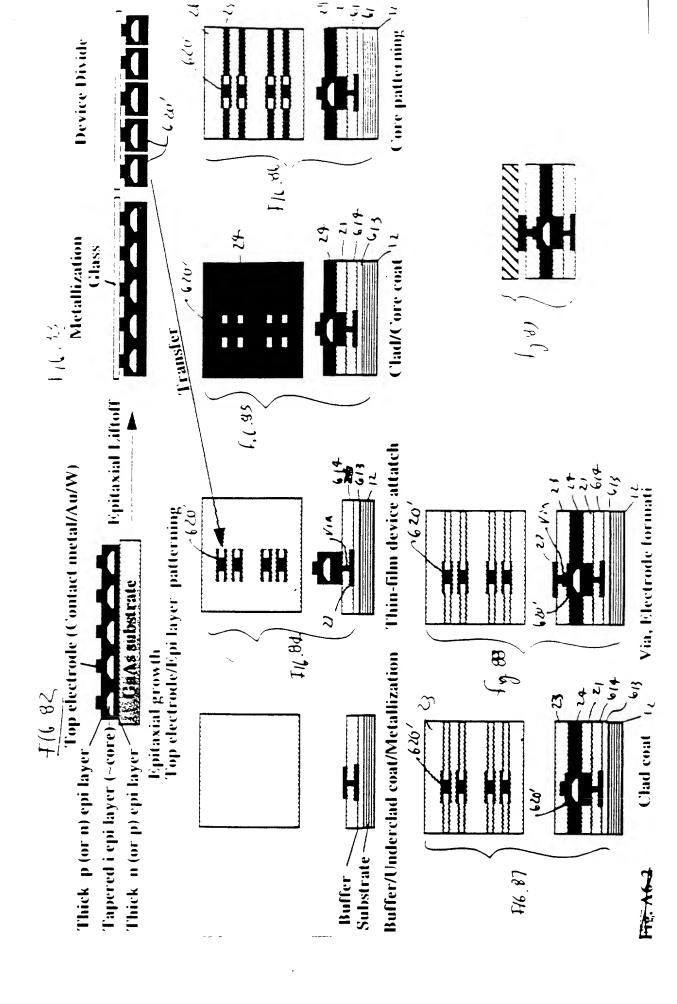
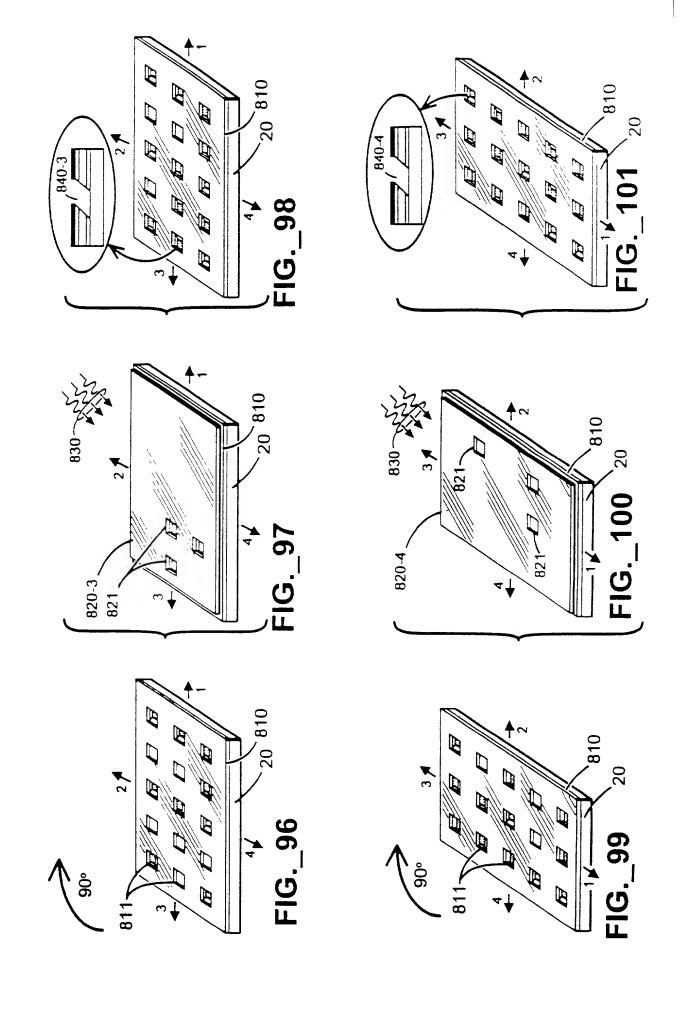
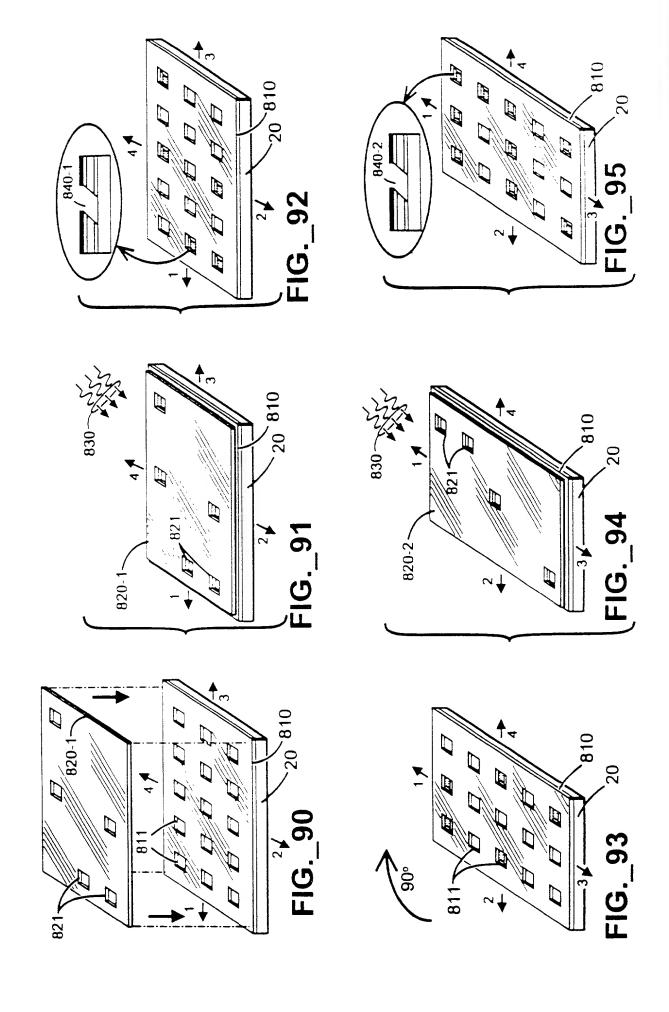


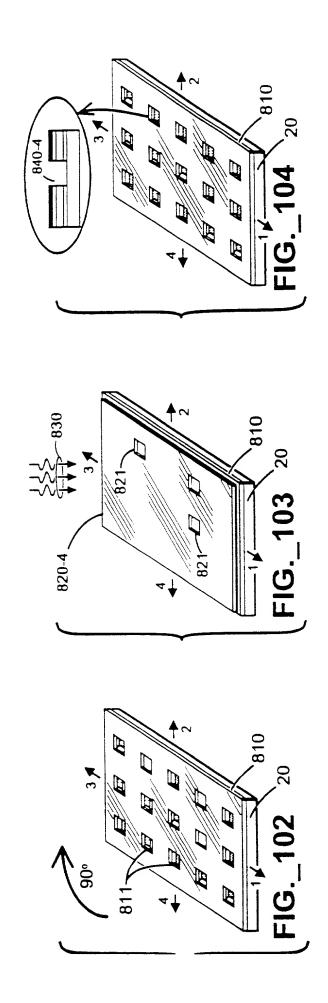
FIG._76 (Transfer)

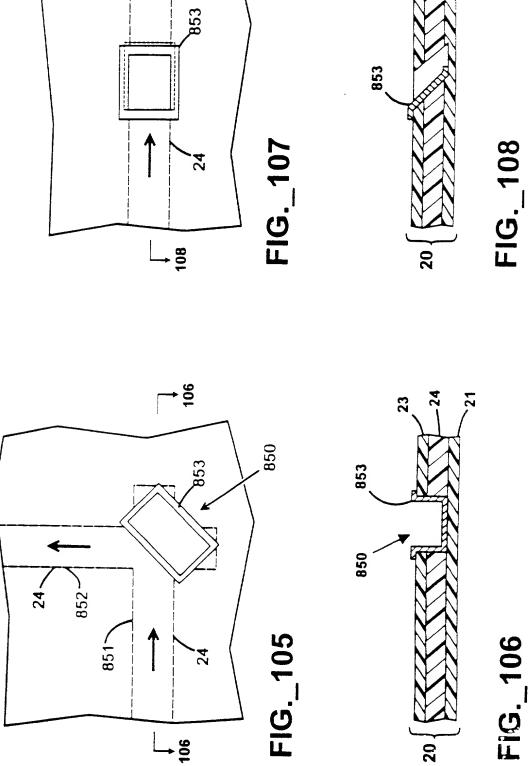










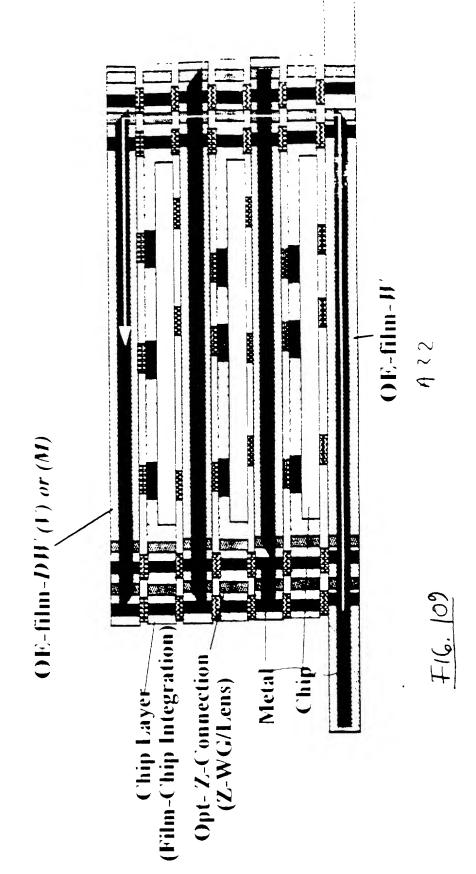


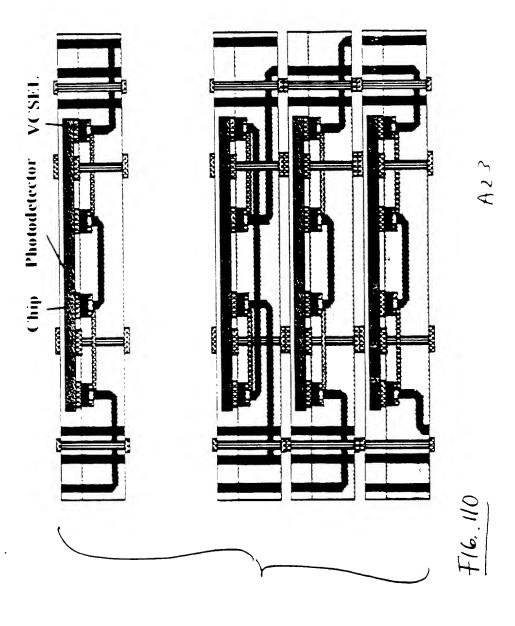
108

FIG._108

FCPT

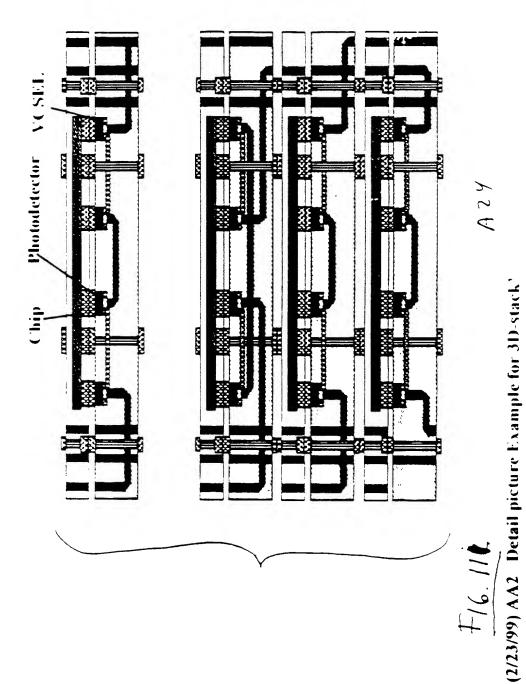
GS CX/CXX OE Solution --- OE-3D-Stack FUNTSU Computer Packaging Technologies, Inc.





(2/23/99) AA1 Detail picture Example for 3D-stack)

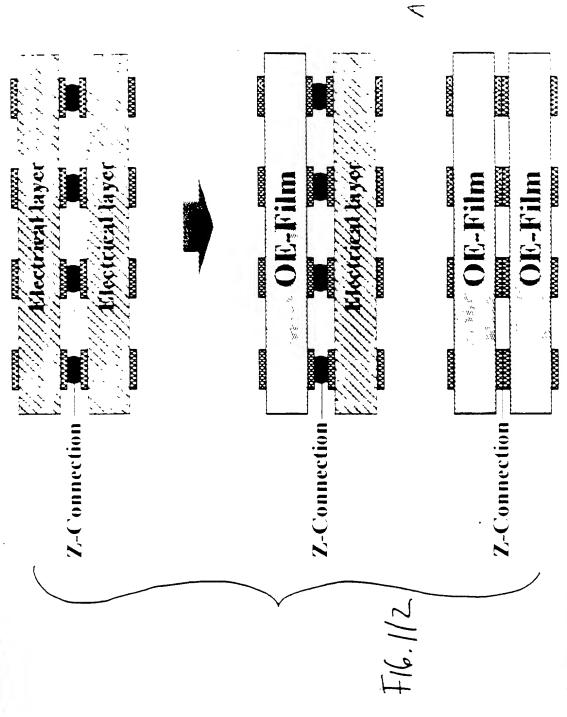
(New version of the AA1 of 2/5/99)



(New version of the AA2 of 2/5/99)

FUNTSU Computer Packaging Technologies, Inc.

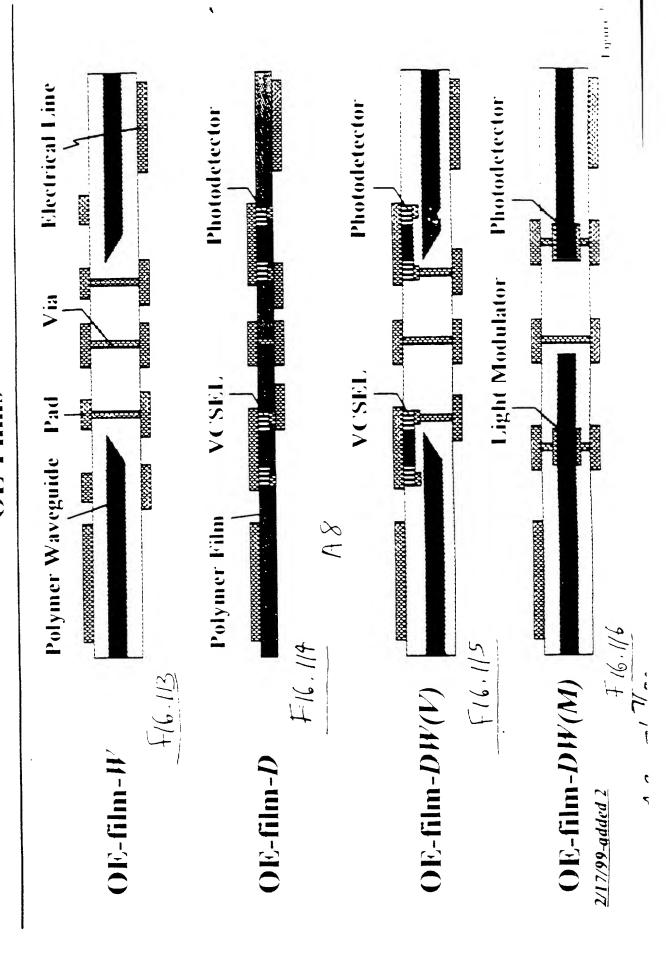
Film/Z-Connection Application to OE-Substrate



2/23/99-added 1

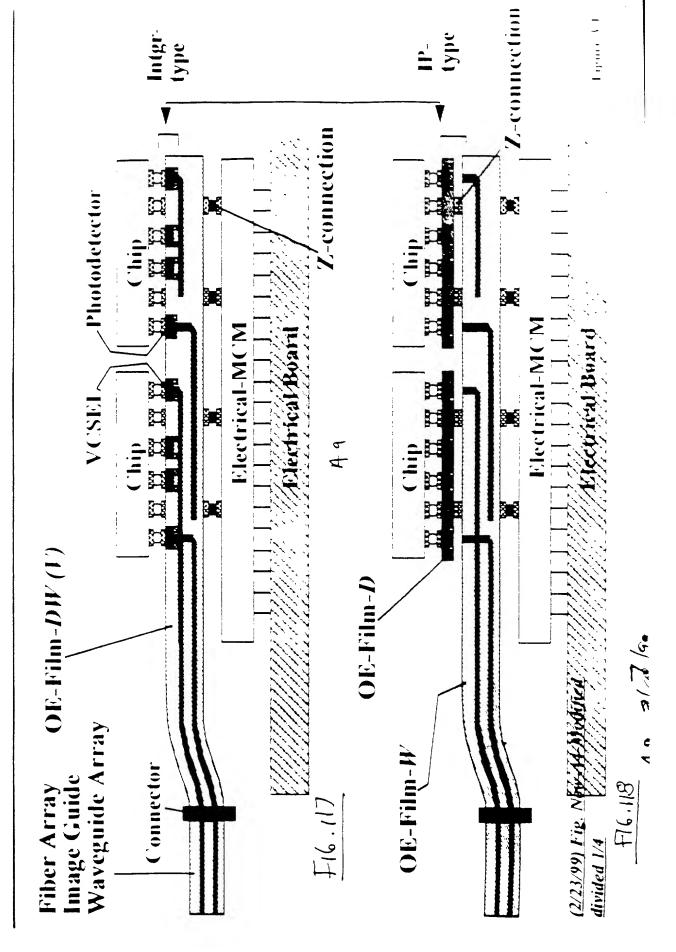
1.111.1

OE-Films FUITSU Computer Packaging Technologies, Inc.



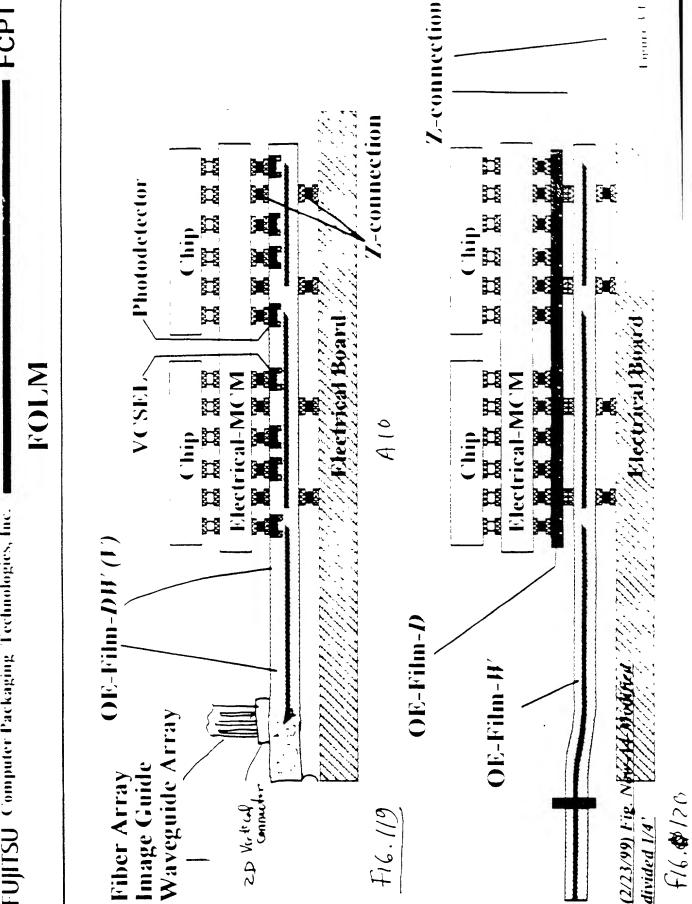
FUJITSU Computer Packaging Technologies, Inc.

FOLM FOLM

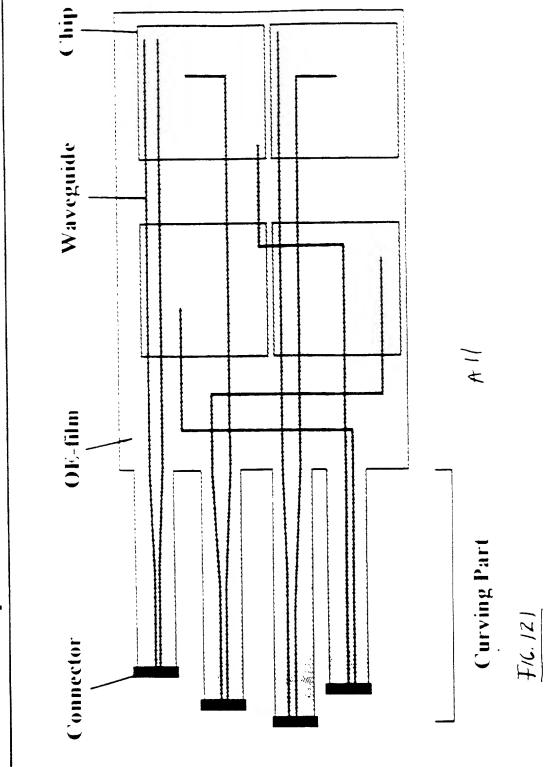


FCPT

FUNTSU Computer Packaging Technologies, Inc.

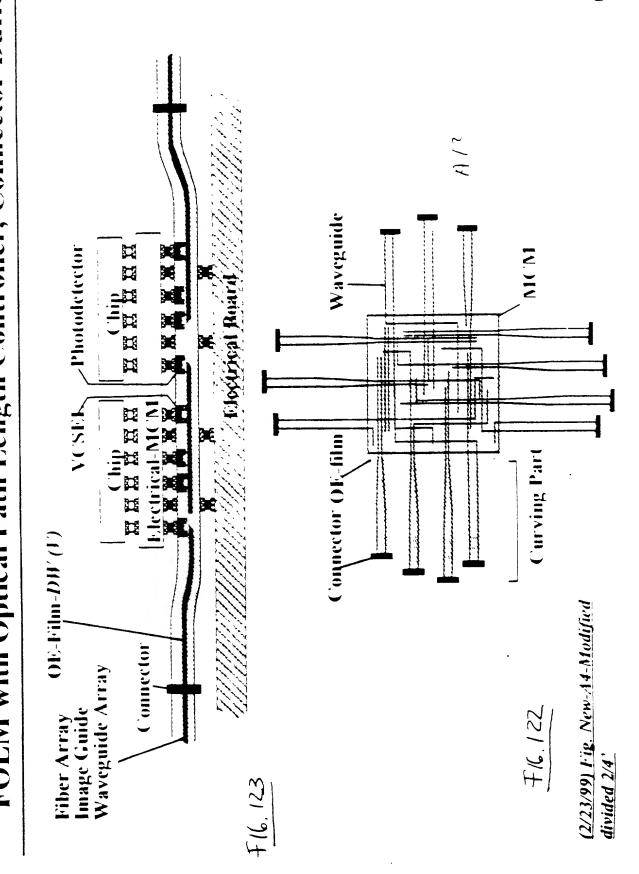


FOLM with Optical Path Length Controller, Connector Buffer FUJITSU Computer Packaging Technologies, Inc.



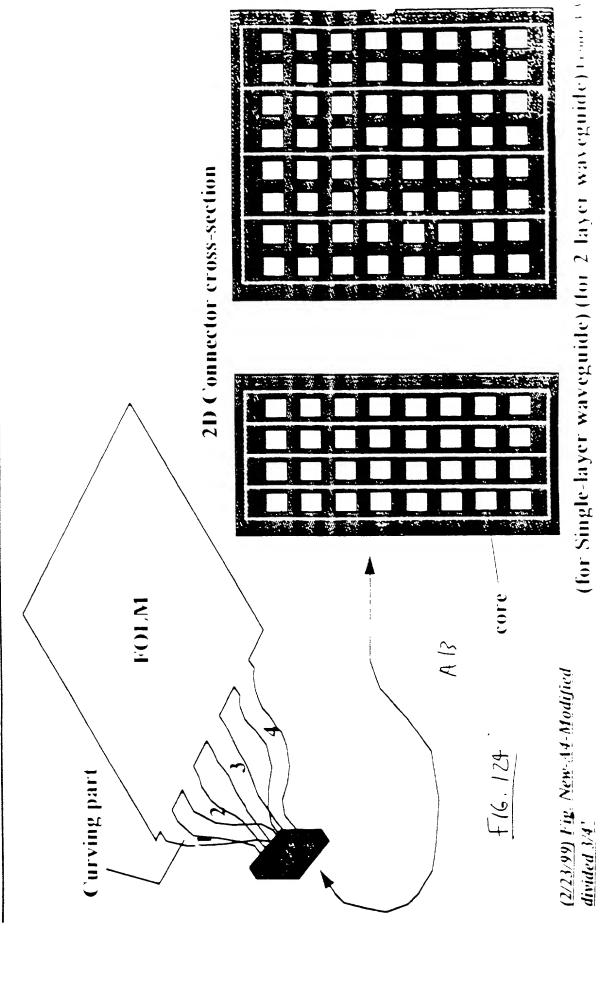
(2/17/99) Fig. New-A4-Modified

■ FCPT FOLM with Optical Path Length Controller, Connector Buffer FUITSU Computer Packaging Technologies, Inc.



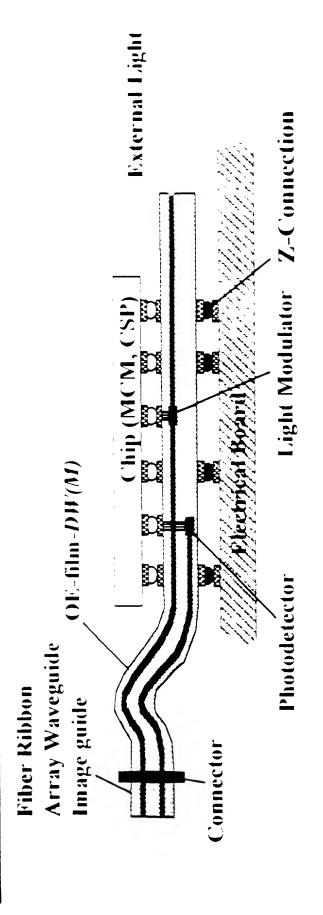
FUJITSU Computer Packaging Technologies, Inc.

FOLM with 2D Waveguide Connector



FUITSU Computer Packaging Technologies, Inc.

FOLM: High-Speed Option

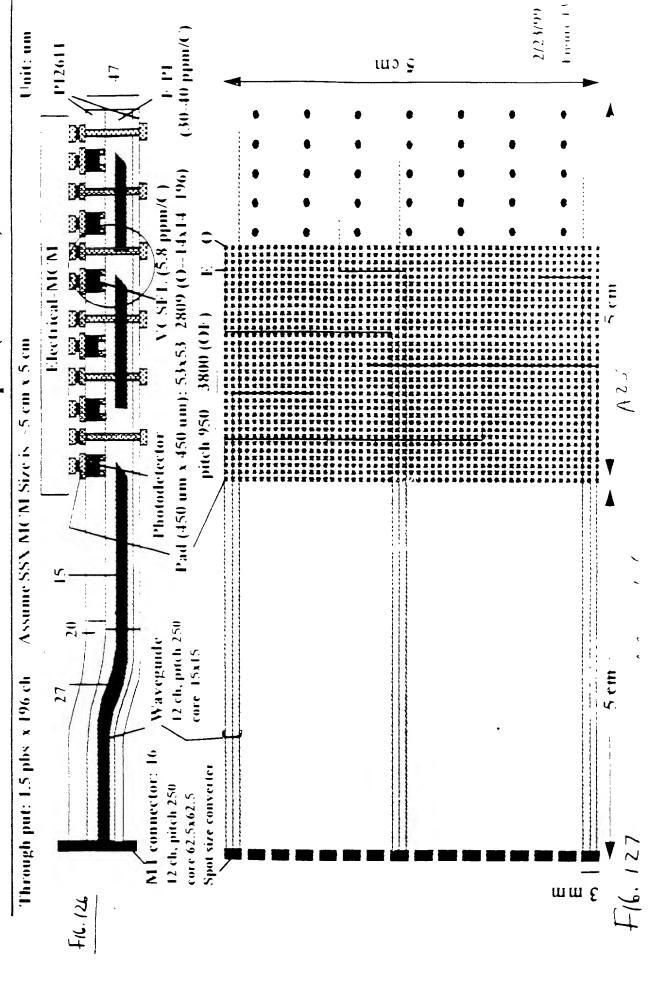


F16.125

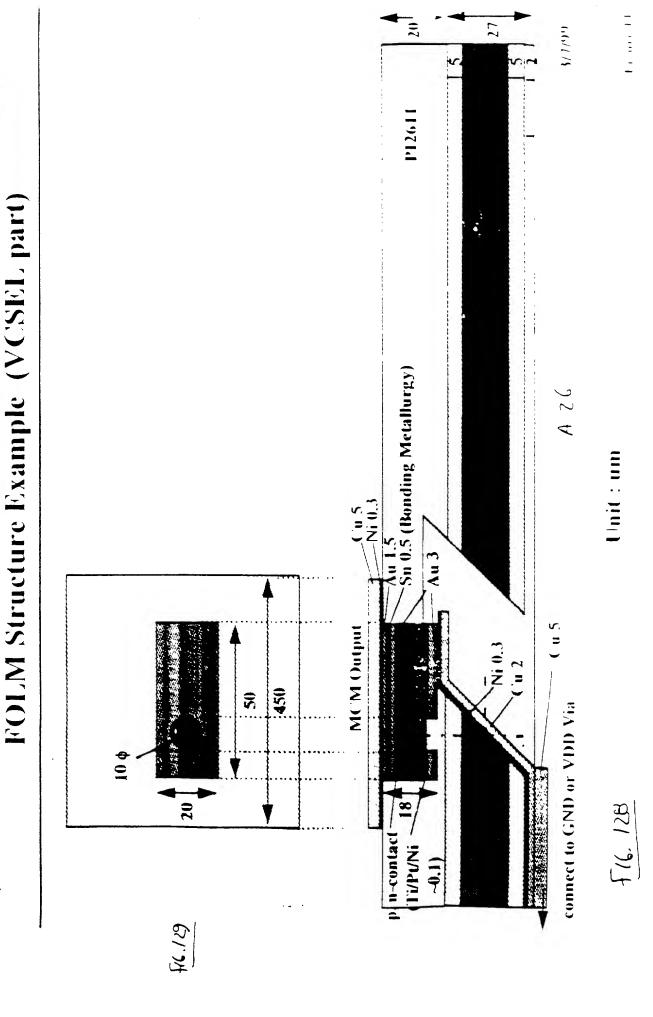
4.14

FUNTSU Computer Packaging Technologies, Inc.

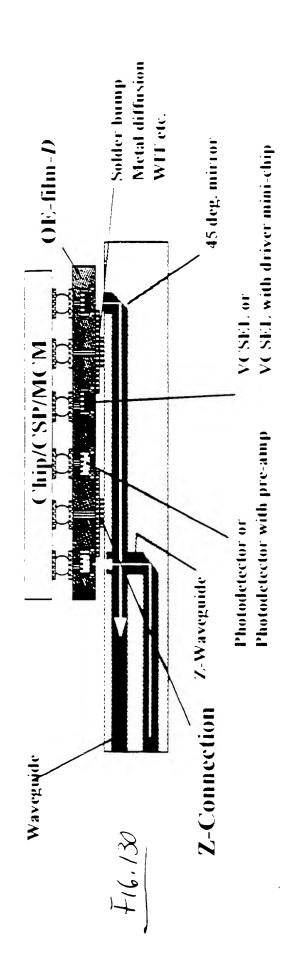
FOLM Structure Example (Overall)

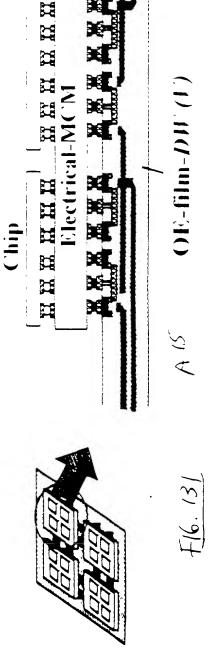


FUJITSU Computer Packaging Technologies, Inc.



OE-film: OE-IP, OE-Film-MCM FUIITSU Computer Packaging Technologies, Inc.





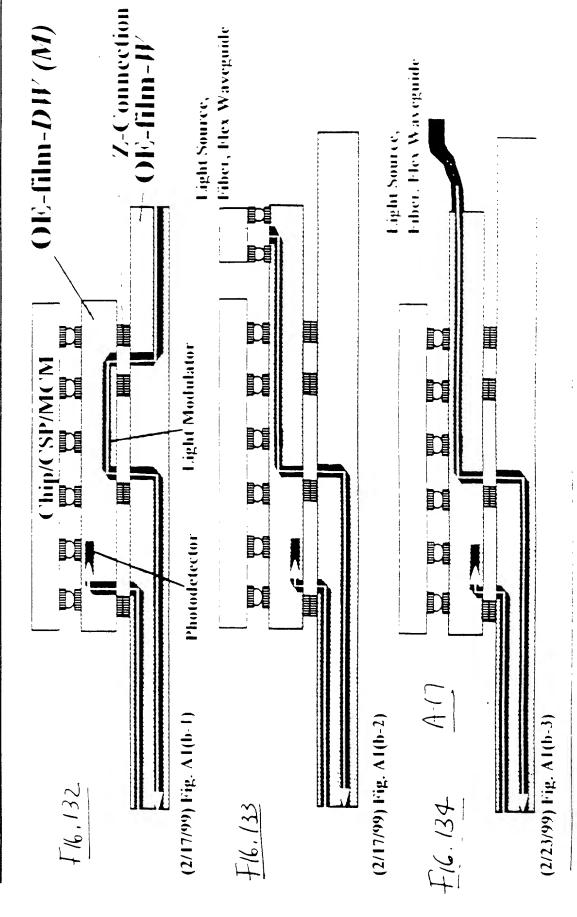
Z-connection

(2/23/99) Fig. New-Al-Modified"

11/2/ 115 2/2/99 .-

FUITSU Computer Packaging Technologies, Inc.

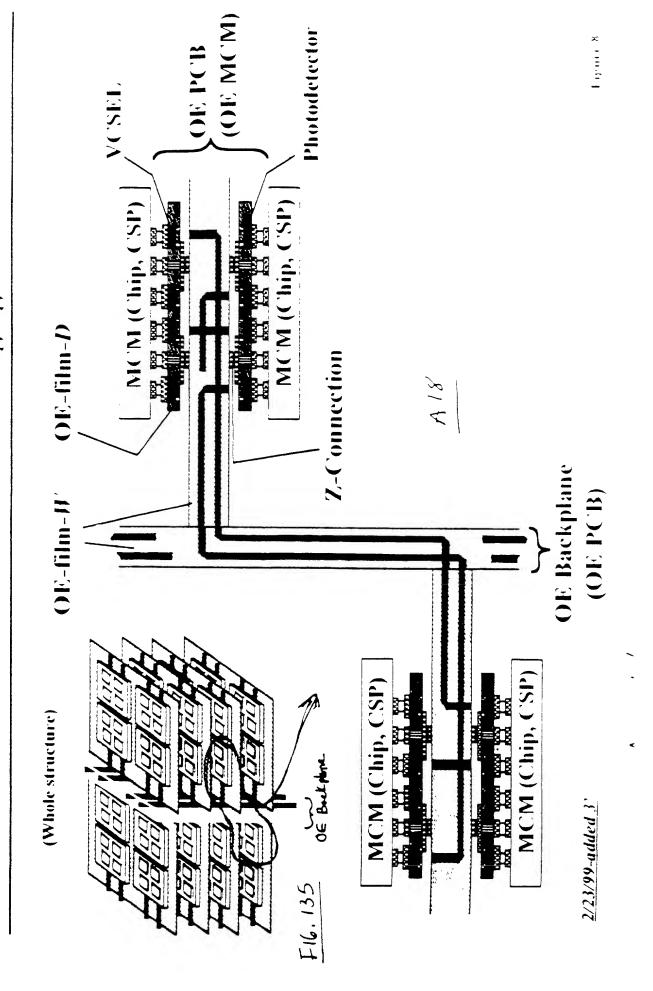
OE-film: Light Modulator Transmitters



Examples of Light Modulators: Electro-Optic (FO) Modulator, Hectro-Absorption (LA) Modulator

FUNTSU Computer Packaging Technologies, Inc.

OE-film: Both-Side Packaging



Line length cont (an actas Z-Connection Photodiode Film Waveguide with Device Integration Direct Jump from LSI L'SI/NIC'NI resetlitiza alalandan samont FUITSU Computer Packaging Technologies, Inc. Fiber Ribbon Connector F16.136

Z Connection

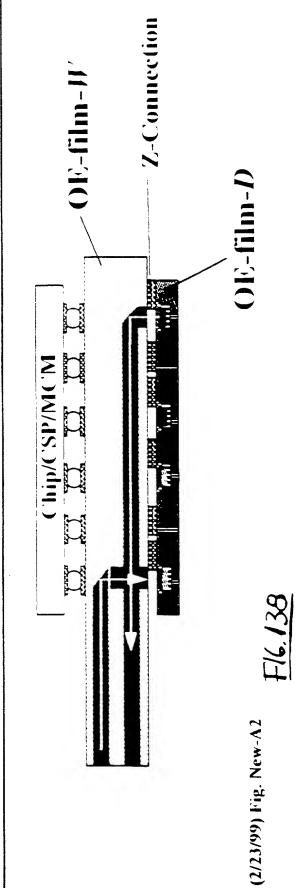
Inght Modulator

Photodetector

Fig. New-. 14-Modified

Computer Packaging Technologies, Inc.

OE IP is Placed on the Oposit Side



A 20

1 grant 10

1-150

FUJISU Computer Packaging Technologies, Inc.

OE MCM

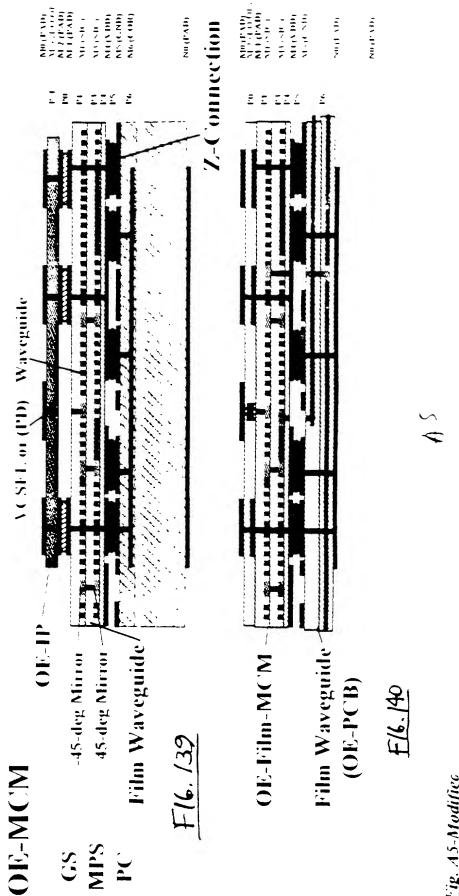
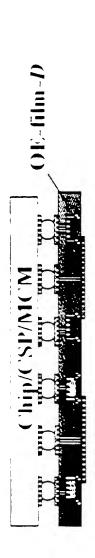


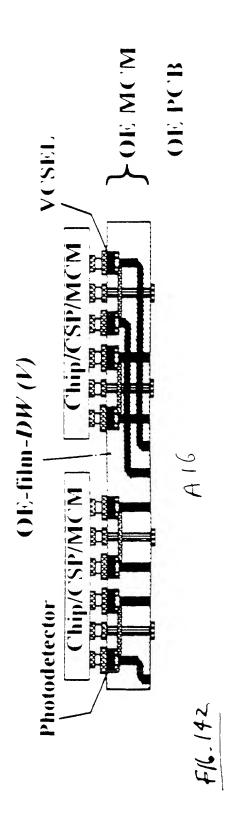
Fig. A5-Modified

FUITSU Computer Packaging Technologies, Inc.

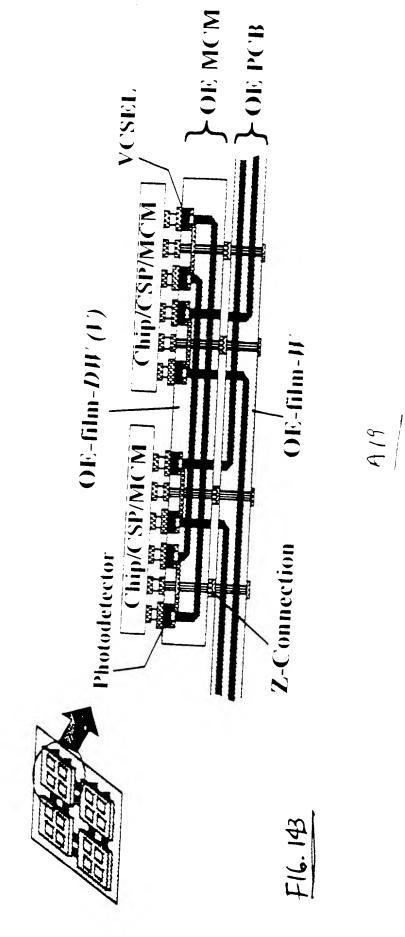
OE-film: Smart Pixel



F/6 /41

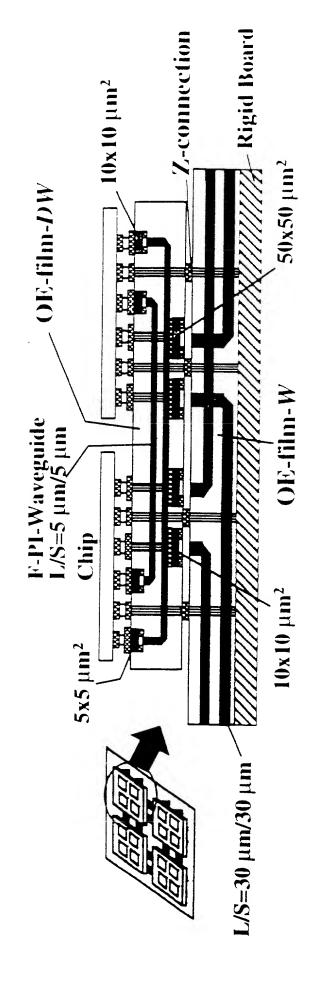


OE-Film/OE-Film Stack --- Back-Side Connection



2/23/99-udded 4"

OE-Film/OE-Film Stack --- Back-Side Connection FUNTSU Computer Packaging Technologies, Inc.



F16 144 Fig. 3/18/99-1

3/7

91/8/18

FUNTSU Computer Packaging Technologies, Inc.

FCP1

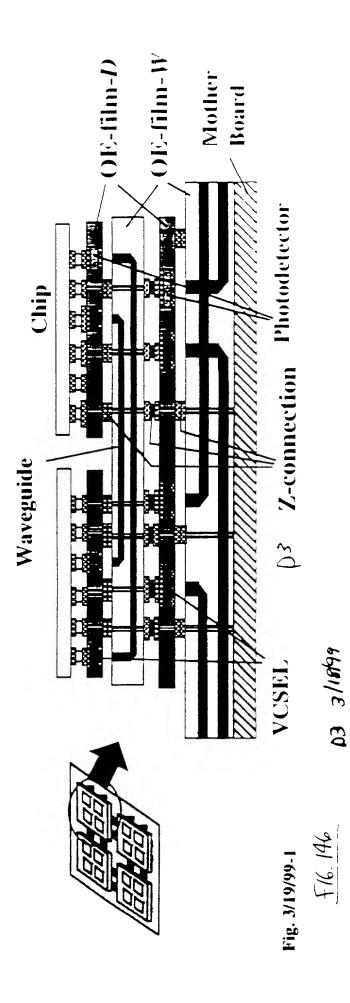
(OE-film-W OE-film-D Mother Board XX XX XX XX XX XX Chip **OE-MCM/OE-Bord Stack Electrical-MCM Mother Boad**

Photodetector

Z-connection

VCSEI

F16. 195



ngysymse olecu

FUJITSU Computer Packaging Technologies, Inc.

Device Integration Process





→ (6) Substrate removal



127

-► (6') Jump to the waveguide formation process

OE-film-DH(1)

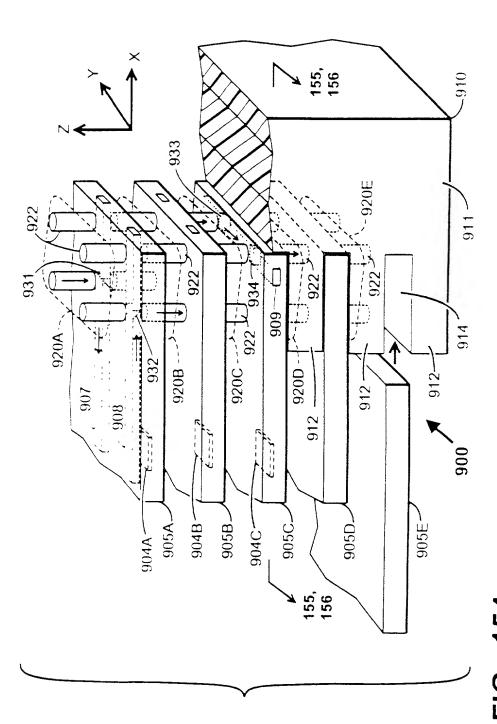
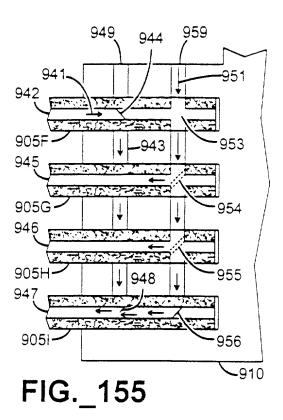
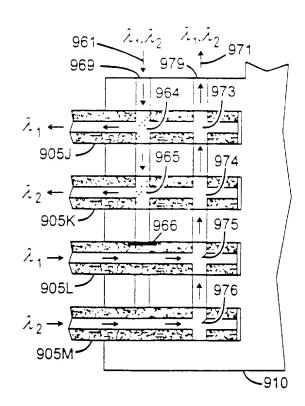


FIG._154

1 /XX





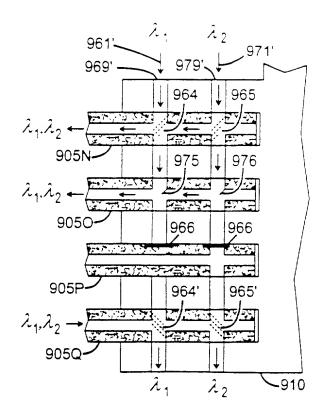
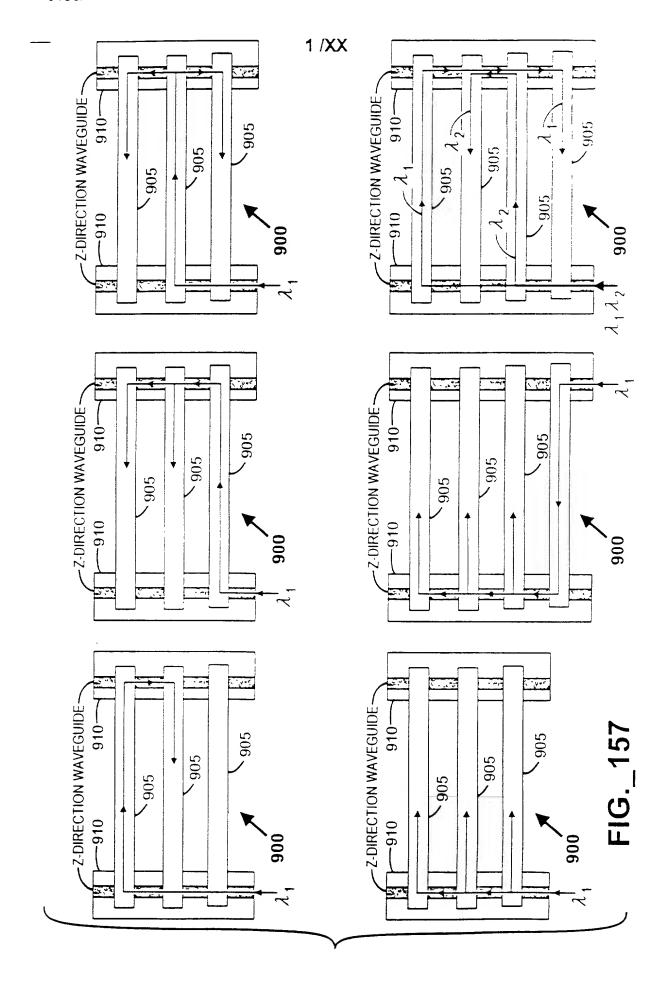
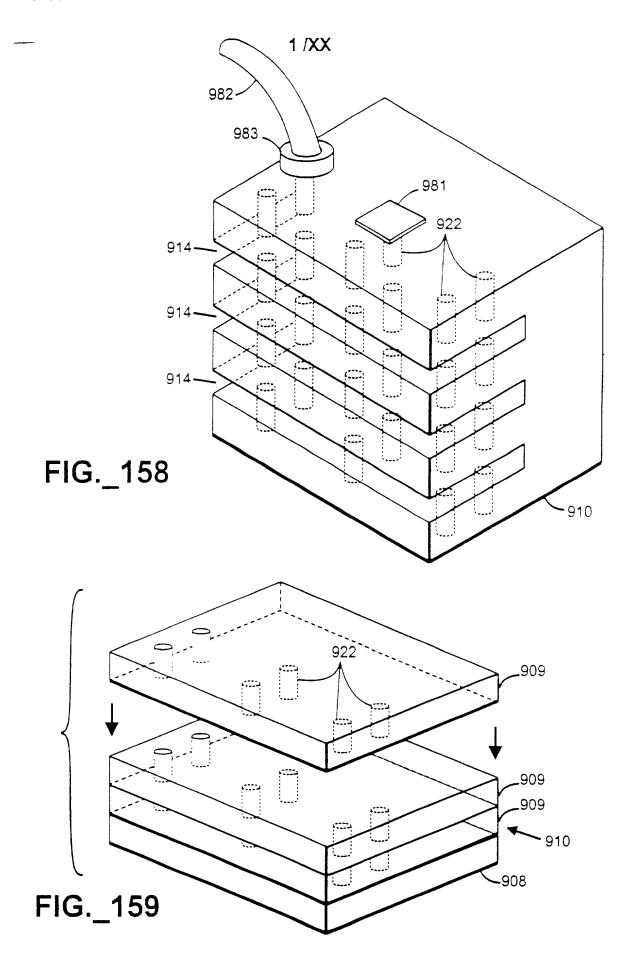
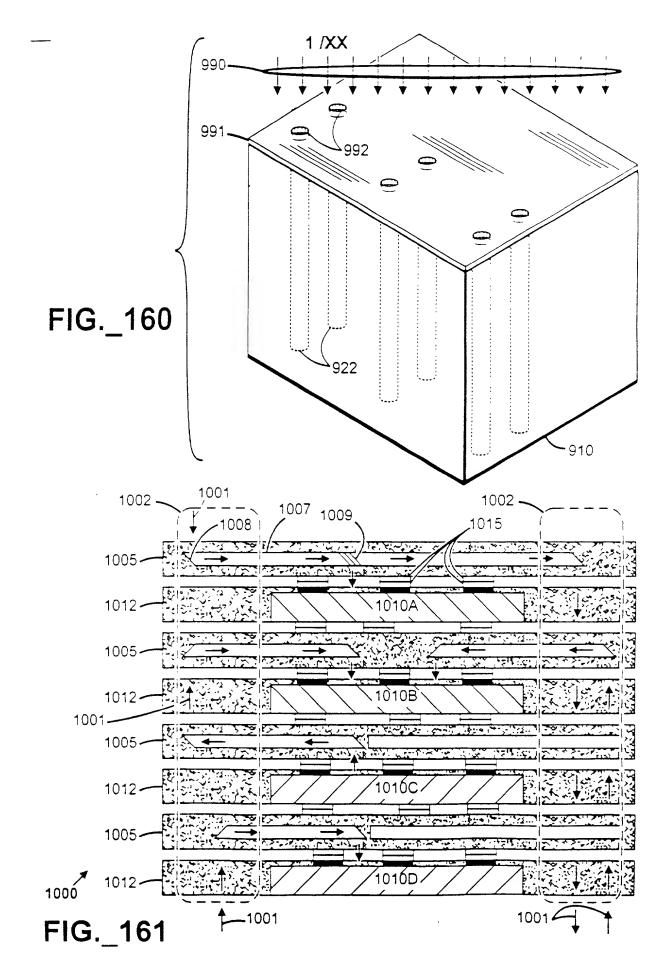


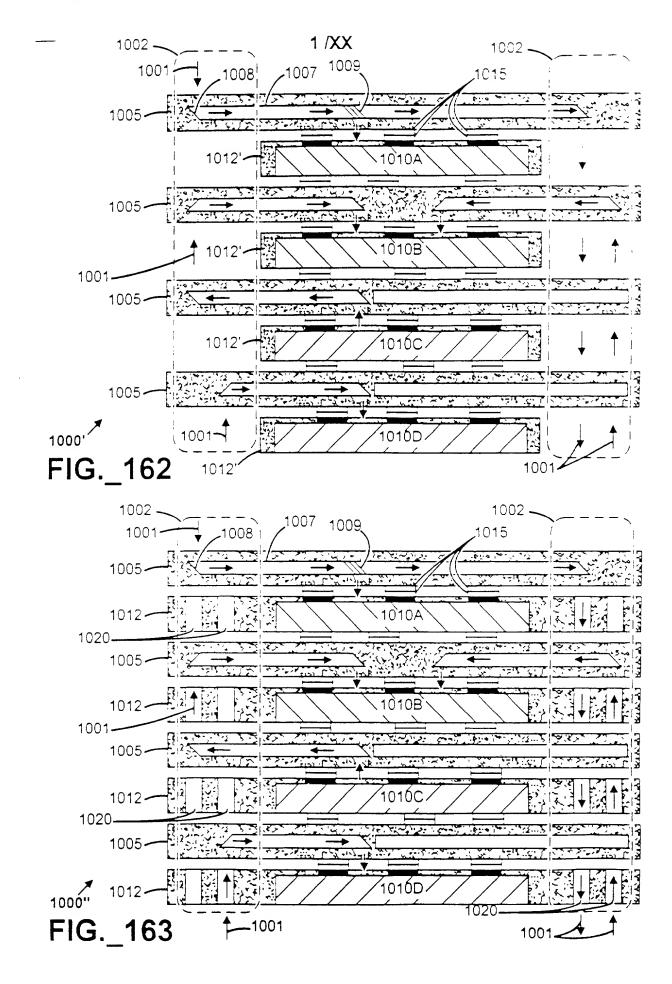
FIG._156-1

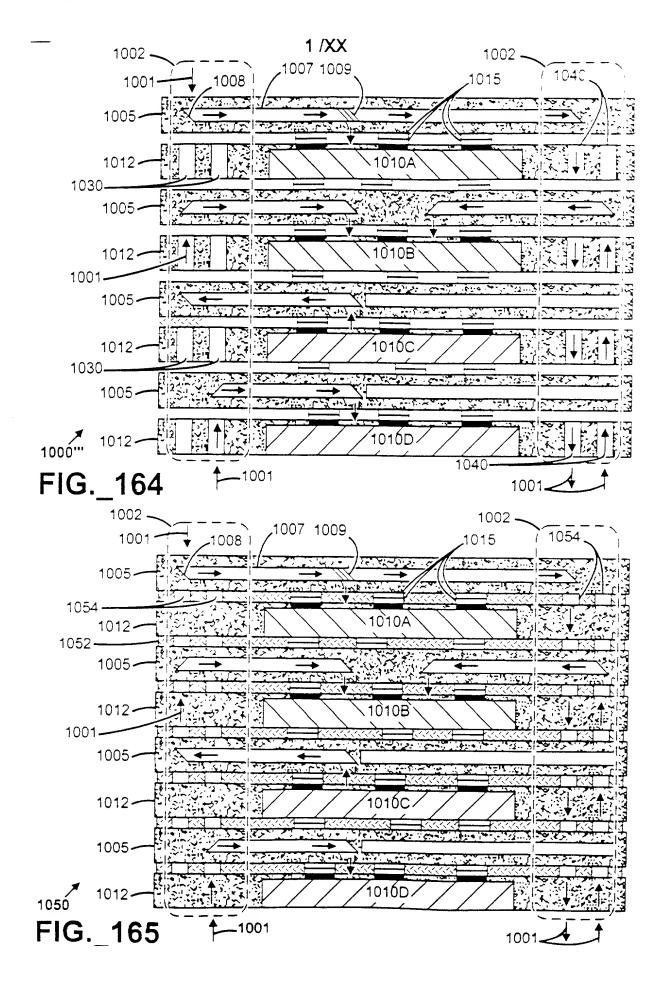
FIG._156-2

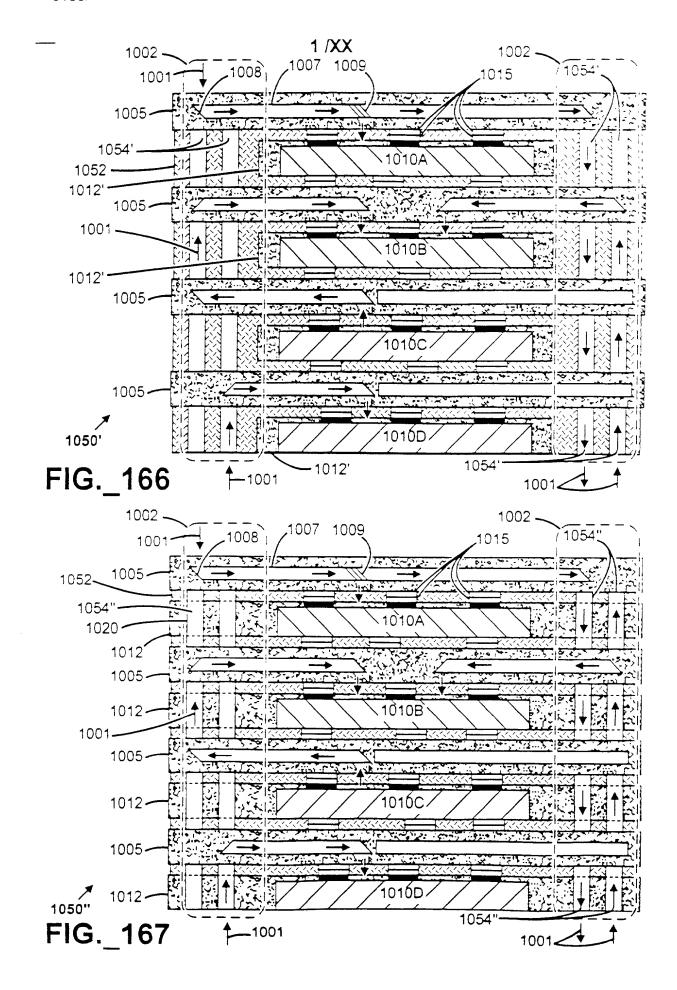


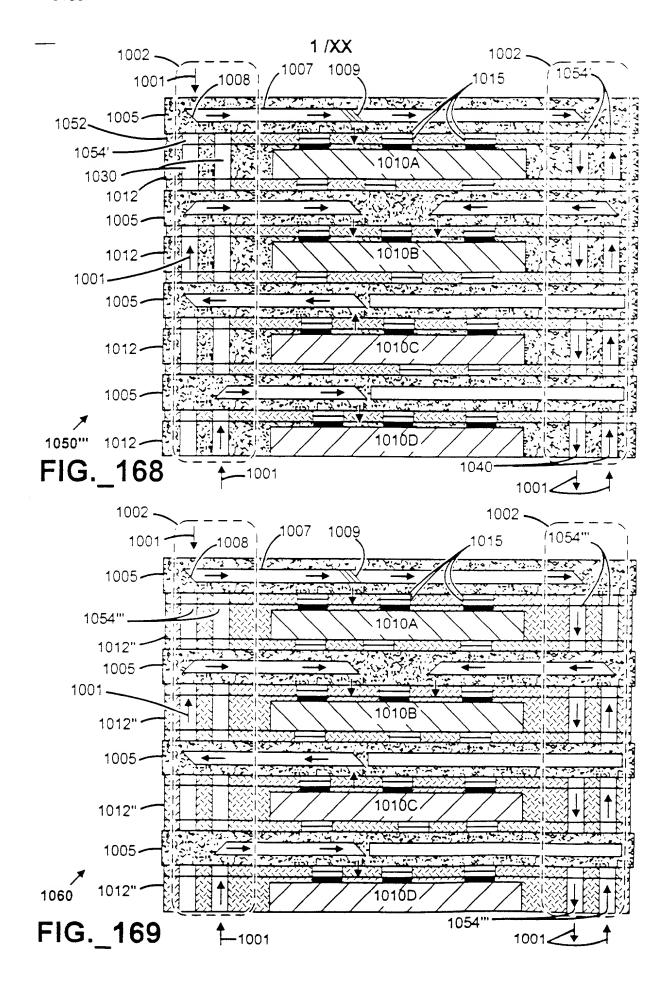












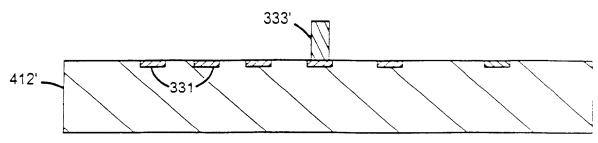


FIG._170

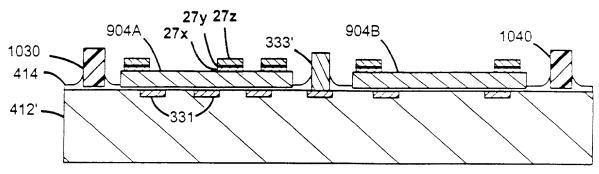


FIG._171

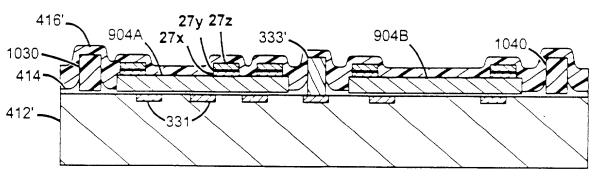


FIG._172

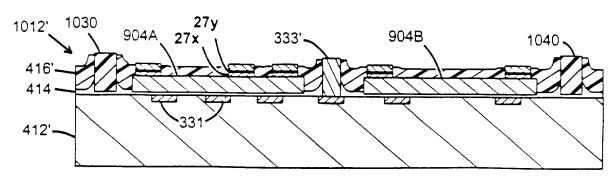


FIG._173

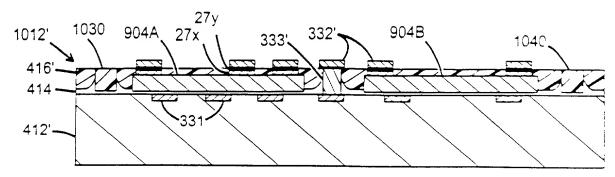


FIG._174

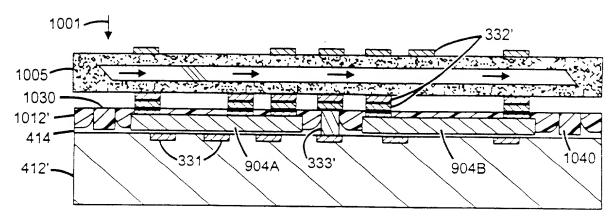
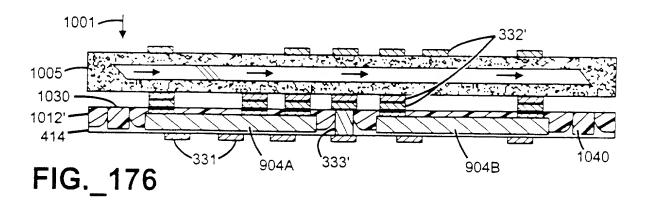


FIG._175



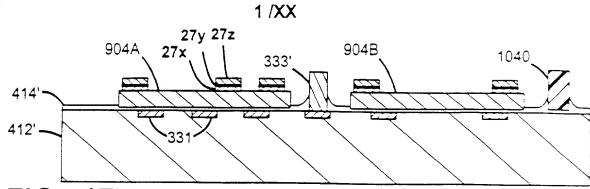


FIG._177

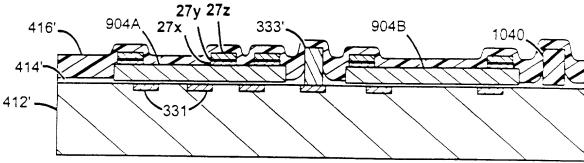


FIG._178

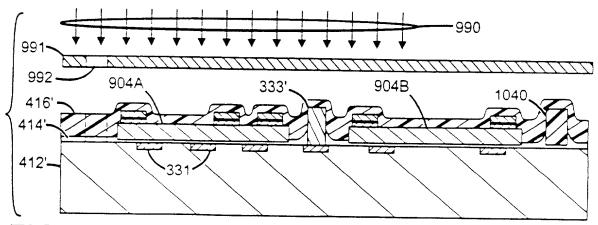


FIG._179

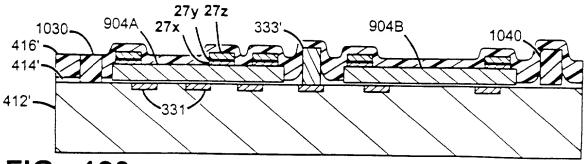


FIG._180

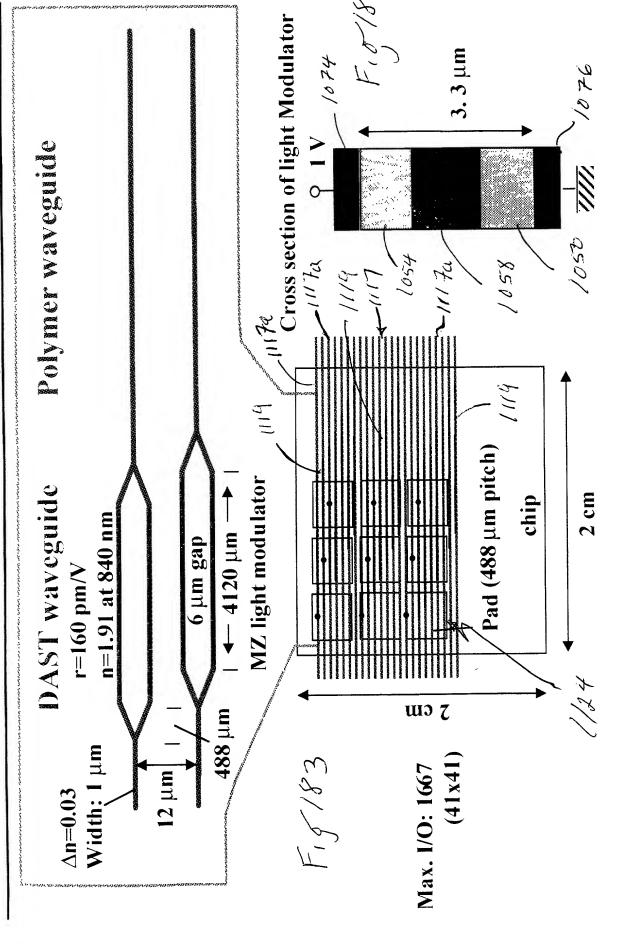
■ FCPT 98-23 12 um pitch) -1030 201101100 Waveguide as of - 10 34 F19/182 I/O Connection in OE Substrate (Planar Modulator) Modulator [4-Layer] 1062 11/2a mm 0**7** 1084 Electrical Substrate Signal I/O count: 6000 = [1500 I/O per Layer]15 mm "hip/MCM 5 mm FUITSU Computer Packaging Technologies, Inc. 0.488 mm 6 um vias can be formed 1098 Photodetector 7011 in blue area Optical Layer Electrical - hsp/ 050 1042 450/ 9401

450/

1050

FUJTSU Computer Packaging Technologies, Inc.

I/O Connection in OE Substrate (Planar Modulator)

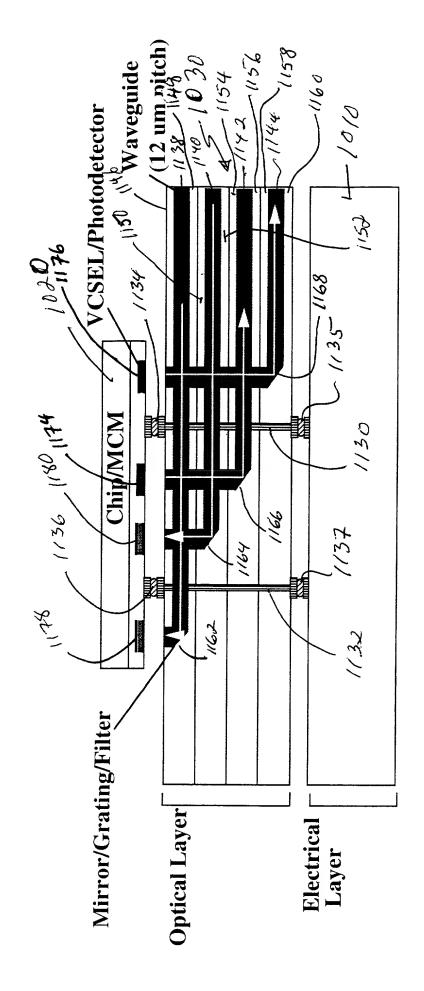


FUITSU Computer Packaging Technologies, Inc.

I/O Connection in OE Substrate (OE-VLSI)

FCPT

Signal I/O count: 6000 = [1500 I/O per Layer] x [4-Layer]



F19185

- FCPT

FUNTSU Computer Packaging Technologies, Inc.

I/O Connection in OE Substrate (OE-VLSI)

Signal I/O count: 6000 = [1500 I/O per Layer] x [4-Layer]

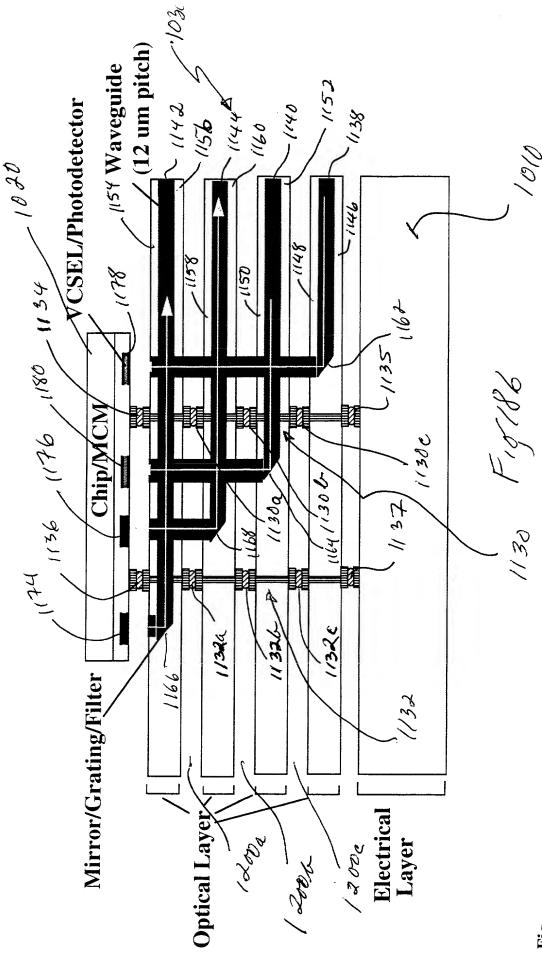


Fig.

FCPT

FUITSU Computer Packaging Technologies, Inc.

I/O Connection in OE Substrate (OE-VLSI, WDM)

///// Waveguide /(12 um pitch) 1206 -1208 VCSEL/Photodetector 1214 1910 UCP ! _ 1246 Signal I/O count: 6000 = [1500 I/O per Layer] x [4-Layer] 1368 1243 Chip/MCM 13066 1260 12084 1280a / Electrical Layer

FIRIBA

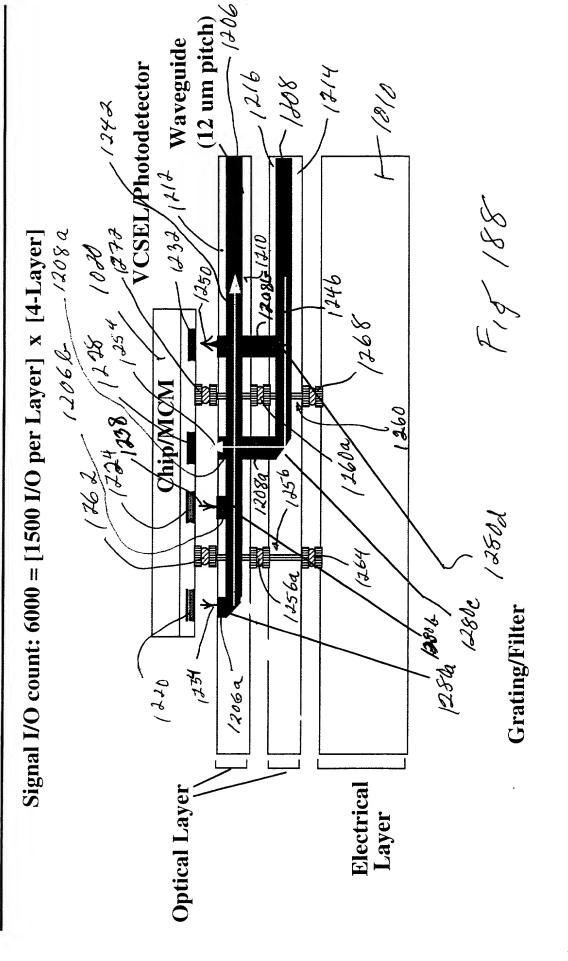
1380/

Grating/Filter

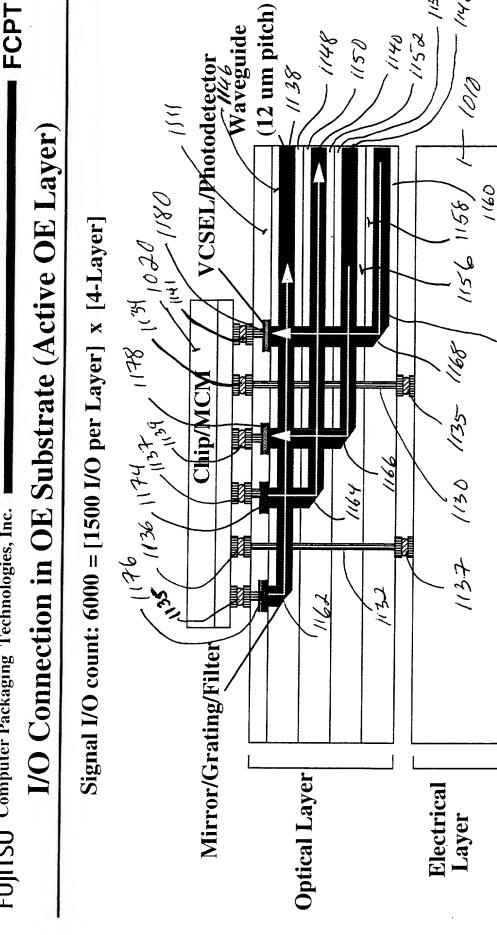
FCPT

FUITSU Computer Packaging Technologies, Inc.

I/O Connection in OE Substrate (OE-VLSI, WDM)



FUITSU Computer Packaging Technologies, Inc.



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FCPT

FUITSU Computer Packaging Technologies, Inc.

I/O Connection in OE Substrate (Active OE Layer)

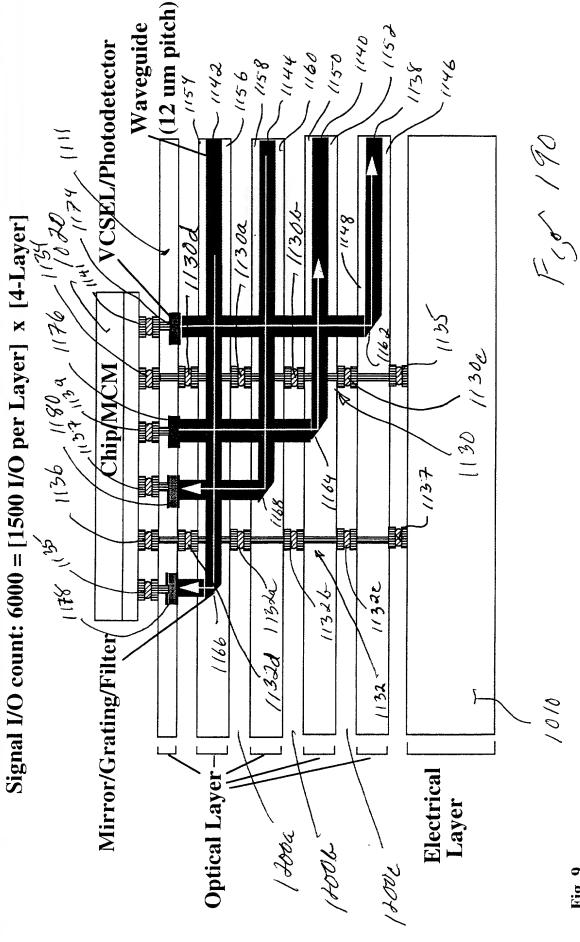


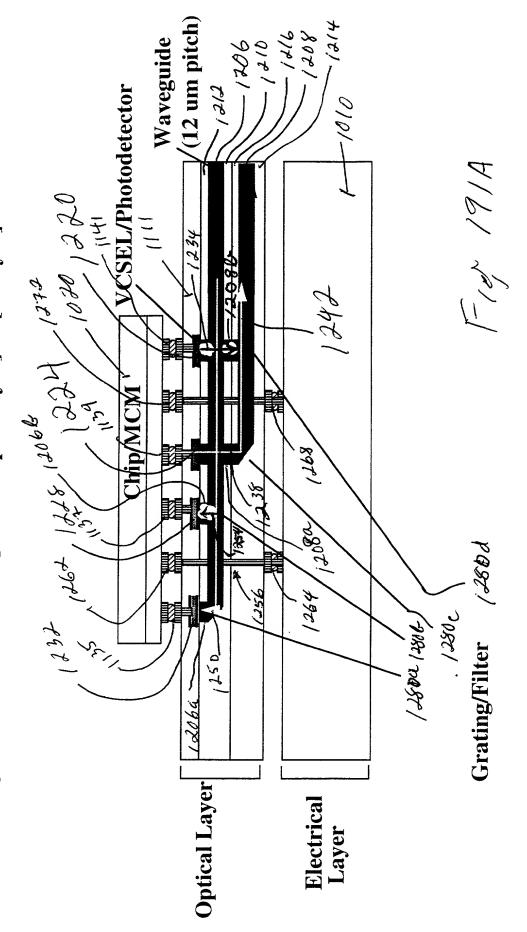
Fig. 9

■ FCPT

FUMTSU Computer Packaging Technologies, Inc.

I/O Connection in OE Substrate (Active OE Layer, WDM)

Signal I/O count: 6000 = [1500 I/O per Layer] x [4-Layer]



■ FCPT

FUNTSU Computer Packaging Technologies, Inc.

I/O Connection in OE Substrate (Active OE Layer, WDM)

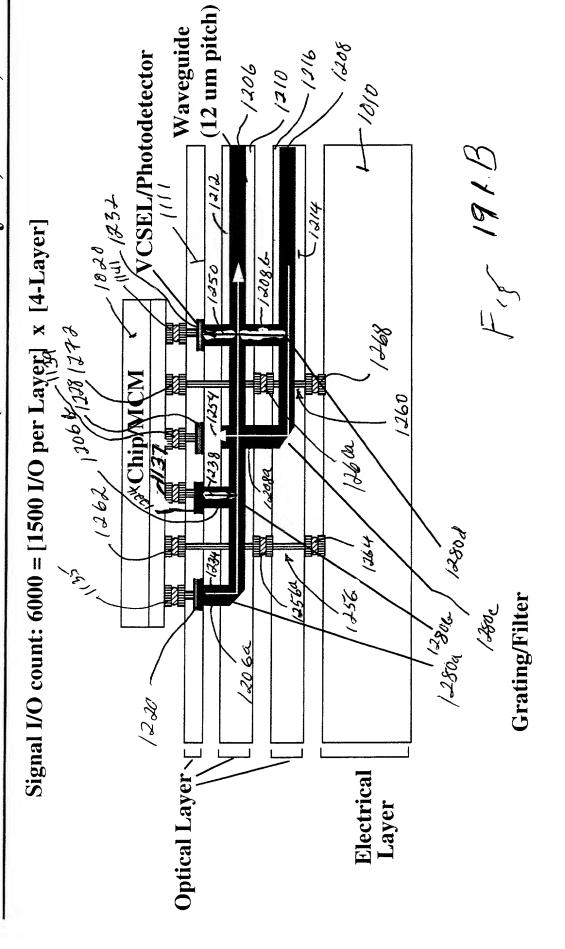
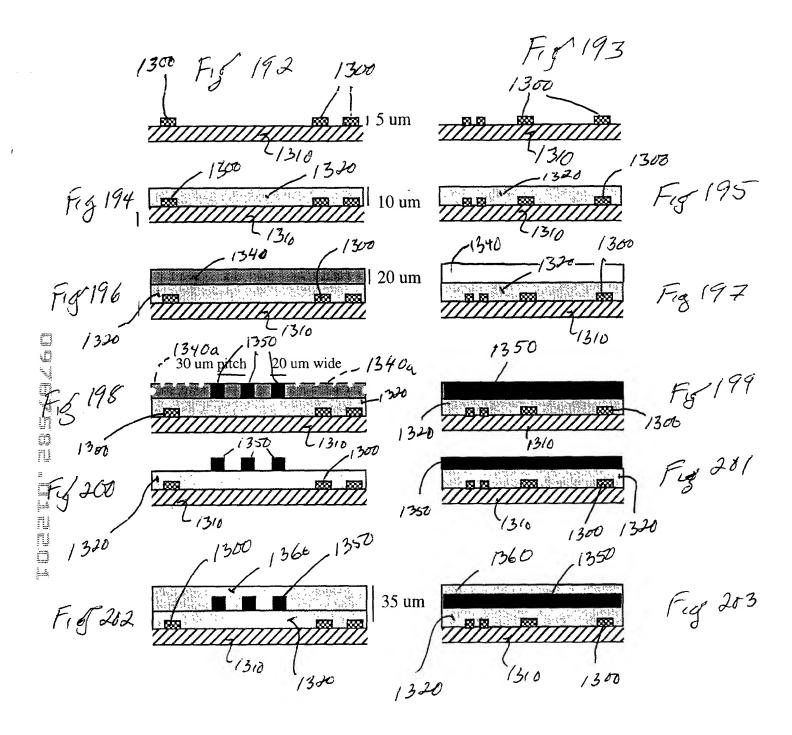
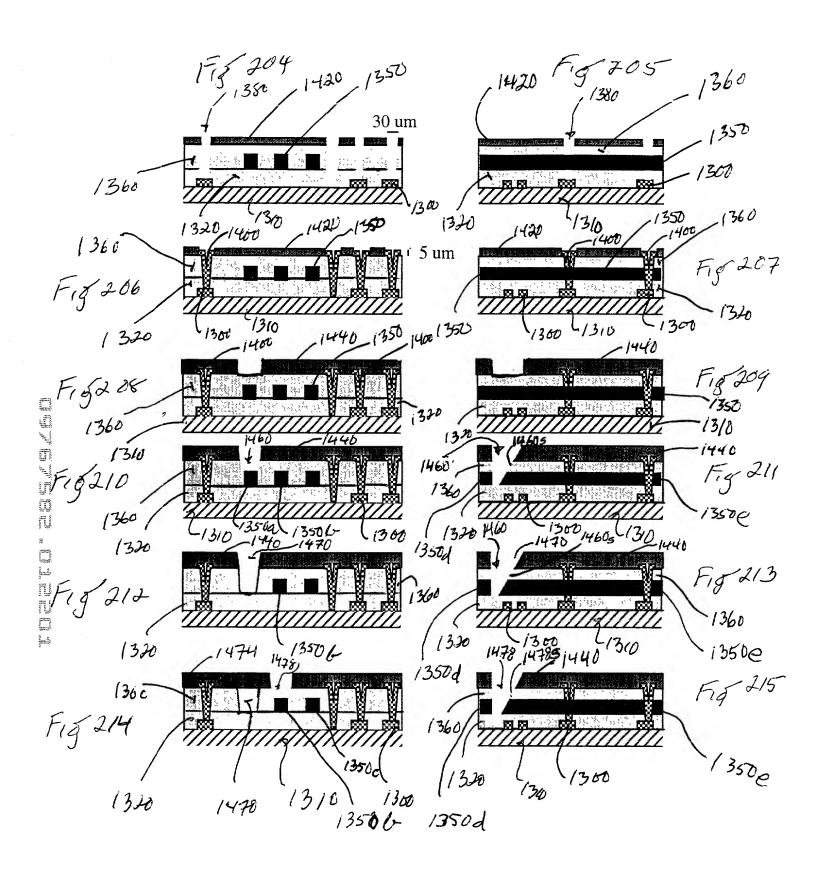
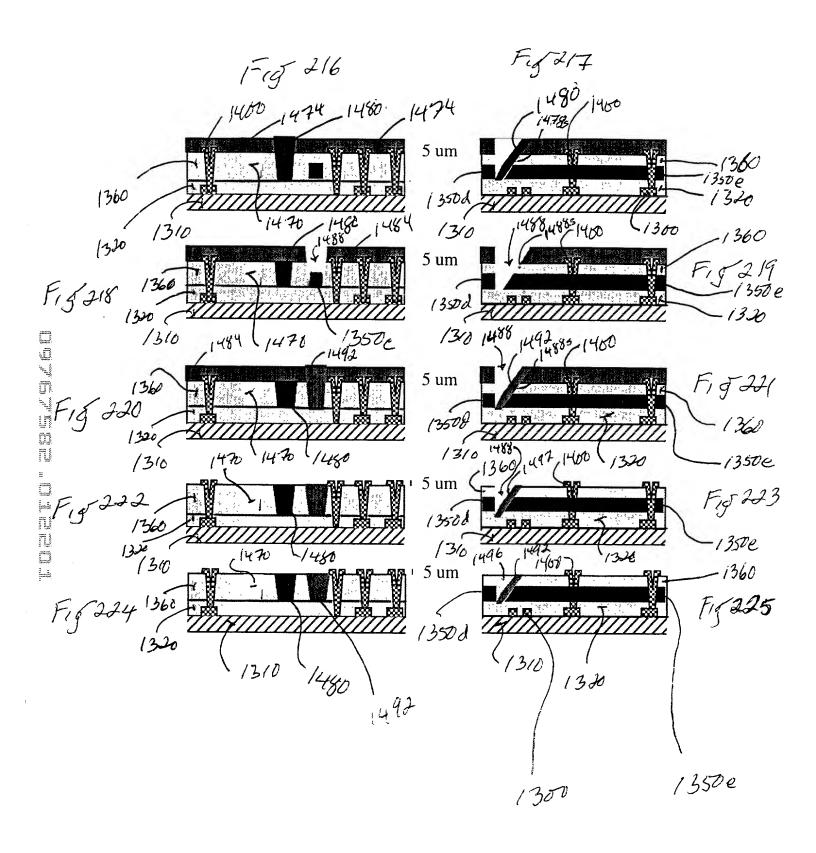
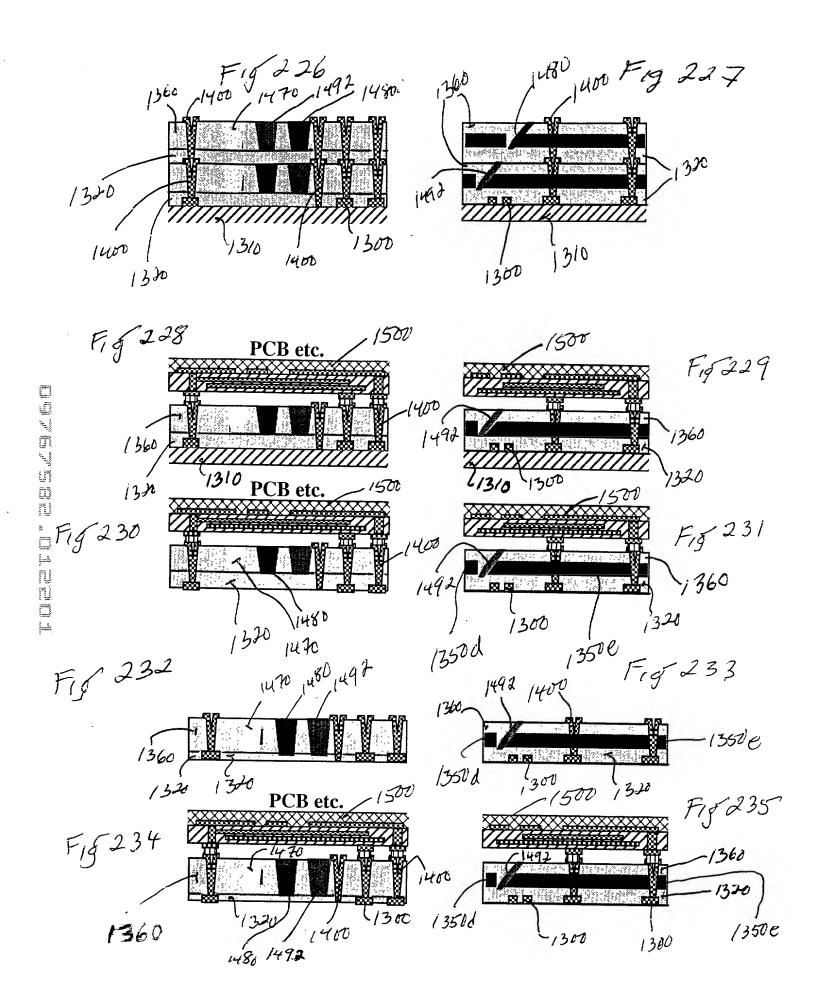


Fig. 11









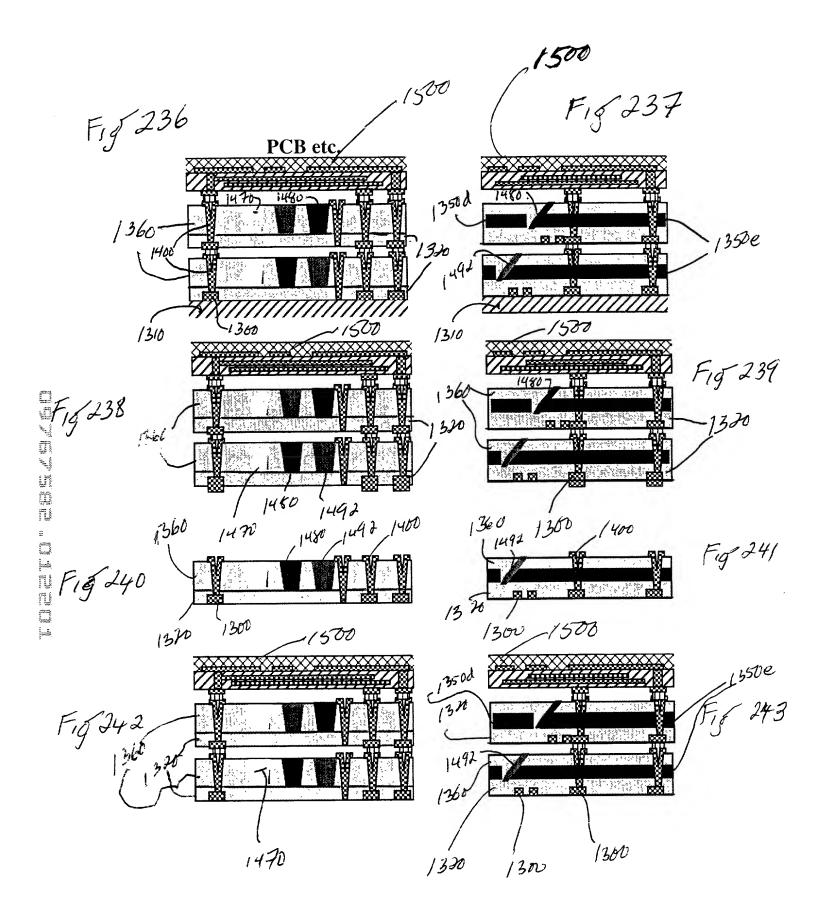
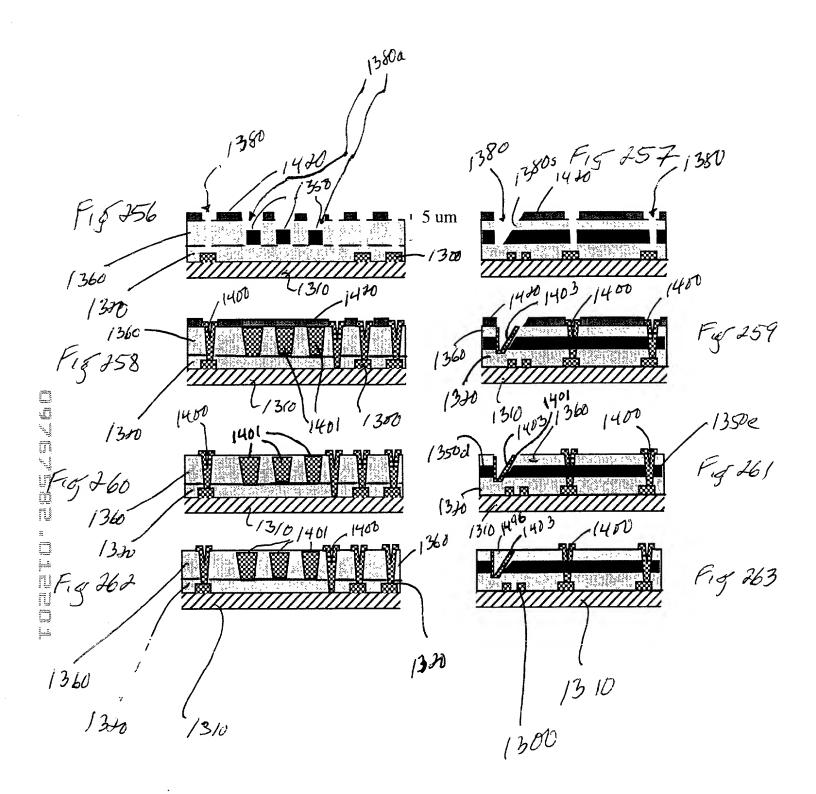
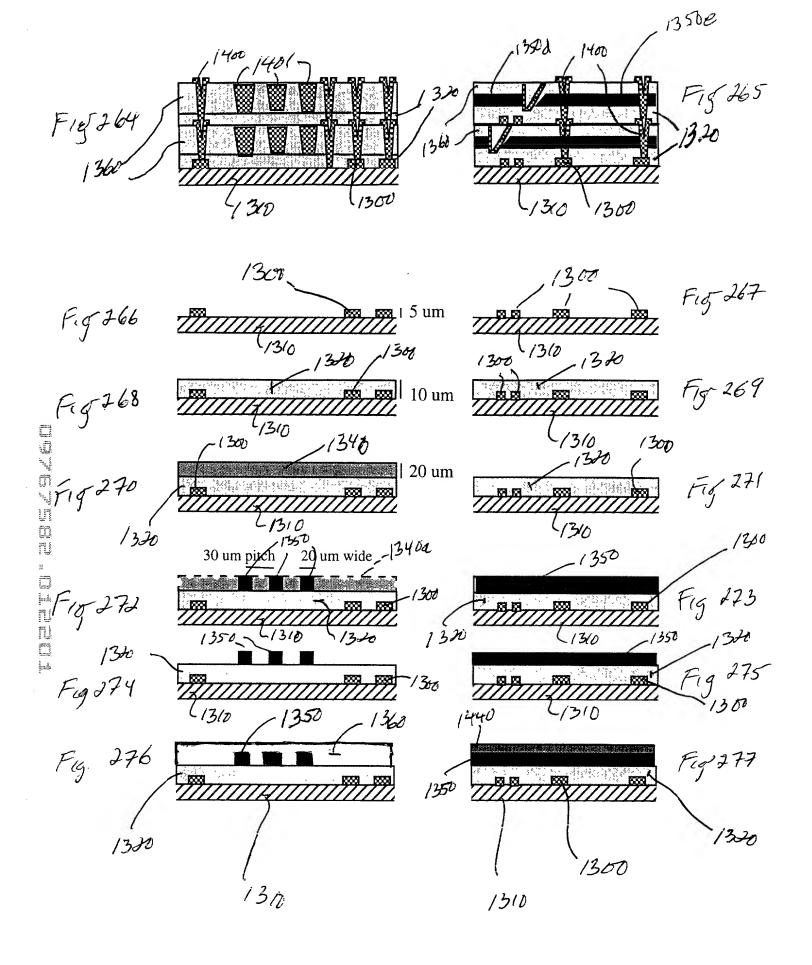
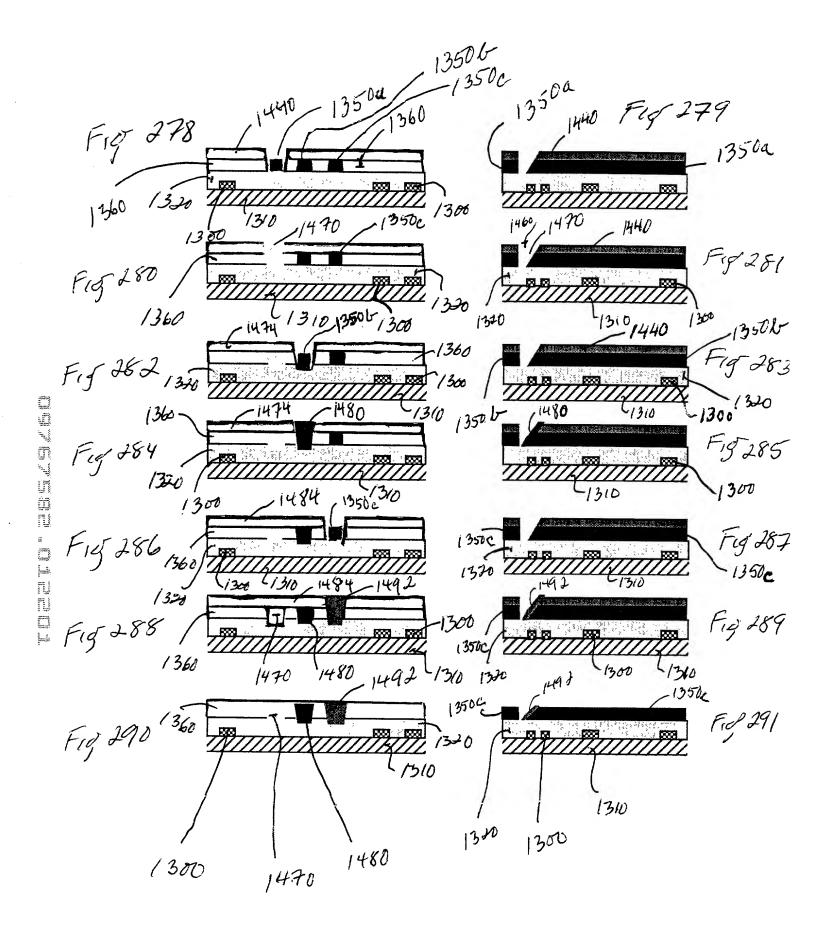
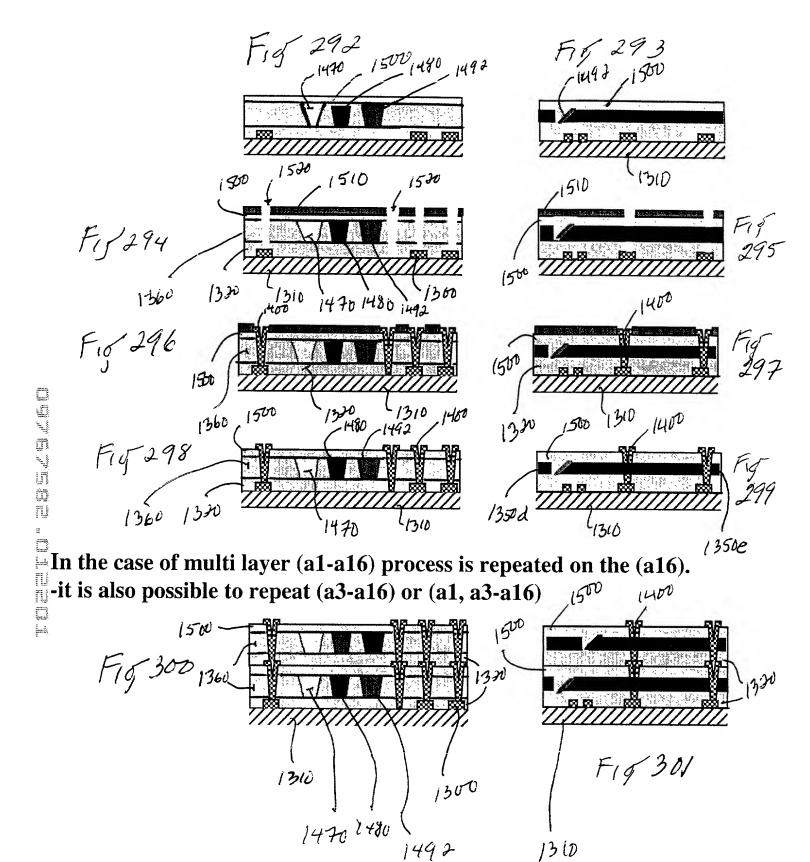


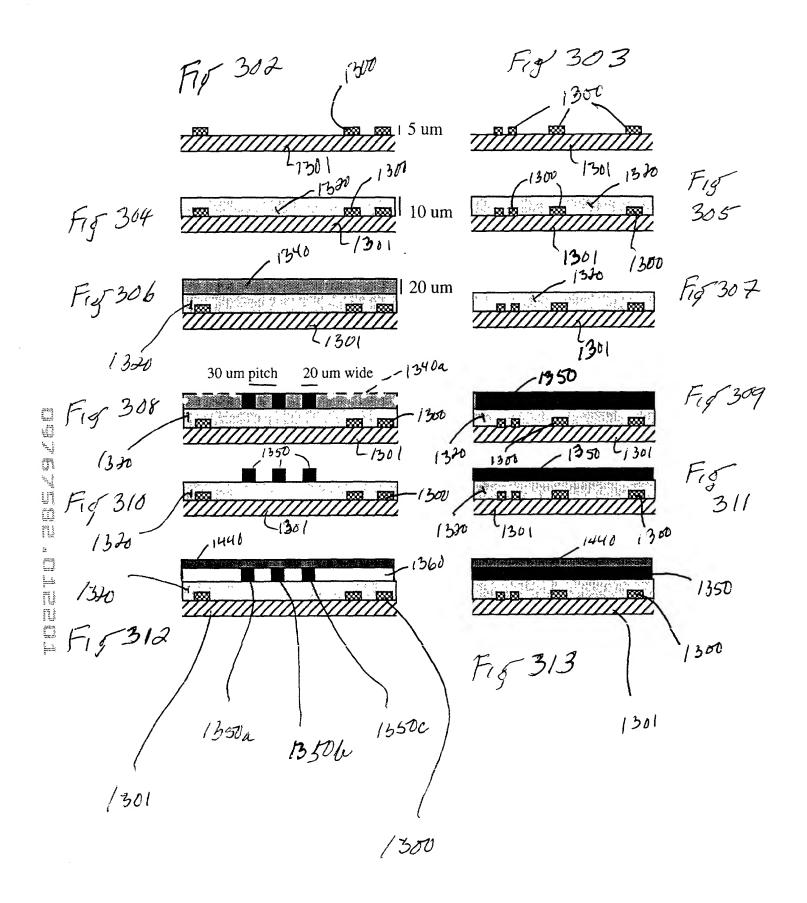
Fig 244 **5 um** 1 5 um 10 um 1340 **20 um** 1300 (320 1348 4 30 um pitch 1310 1310 /310 1300 1350 1360 1350 1360 35 um 13/0 1310 1300 1300

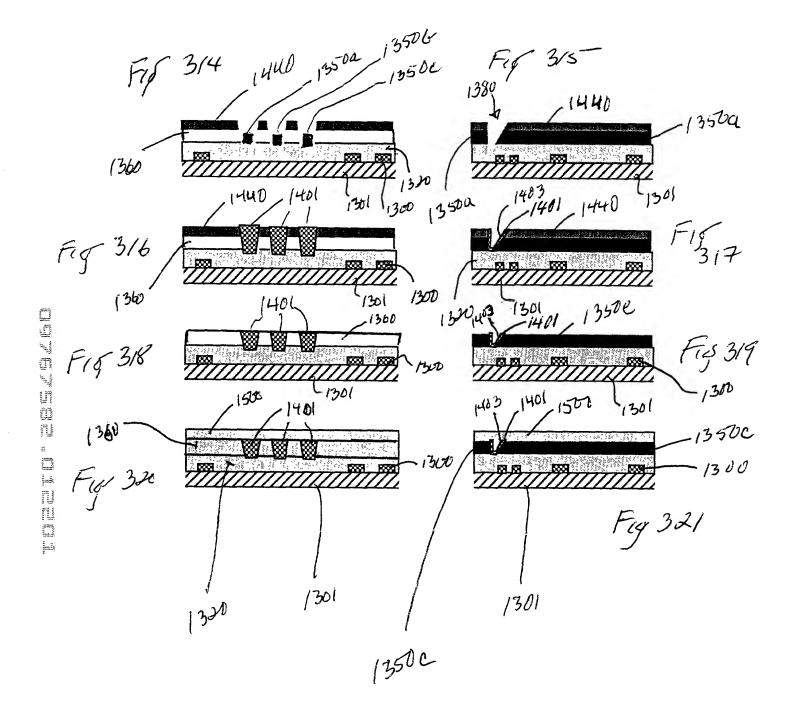


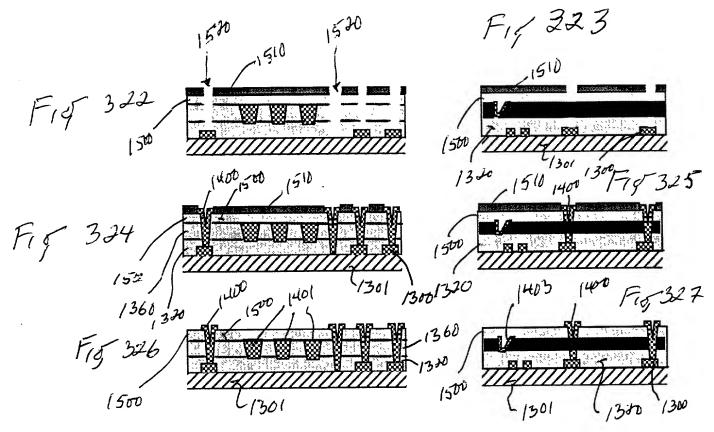




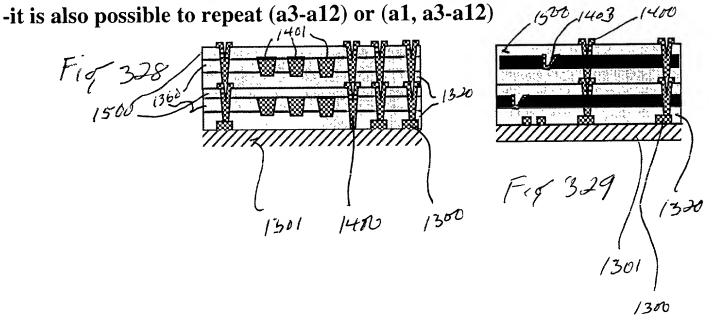




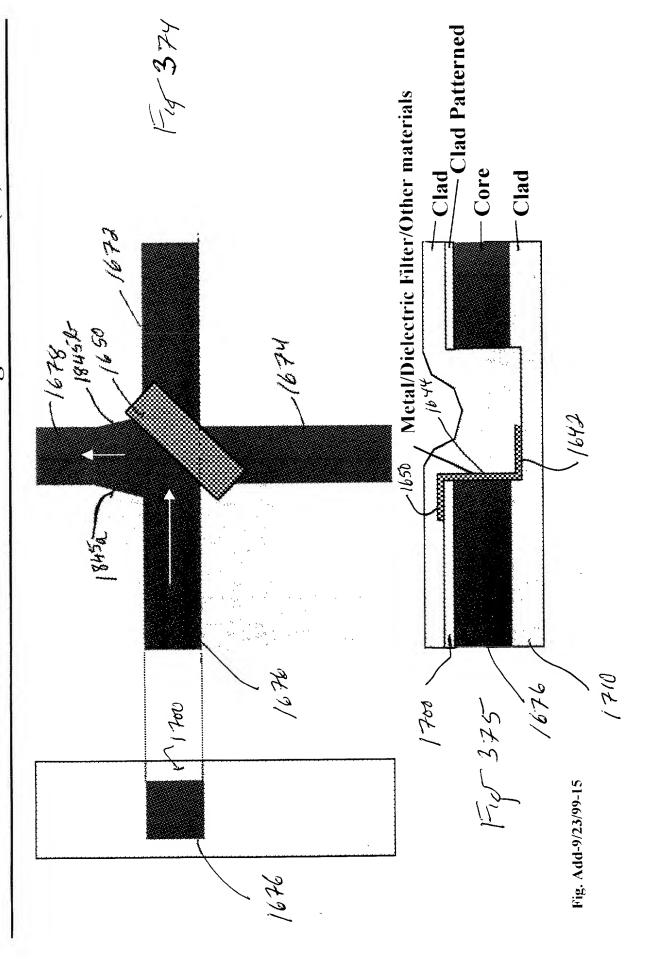


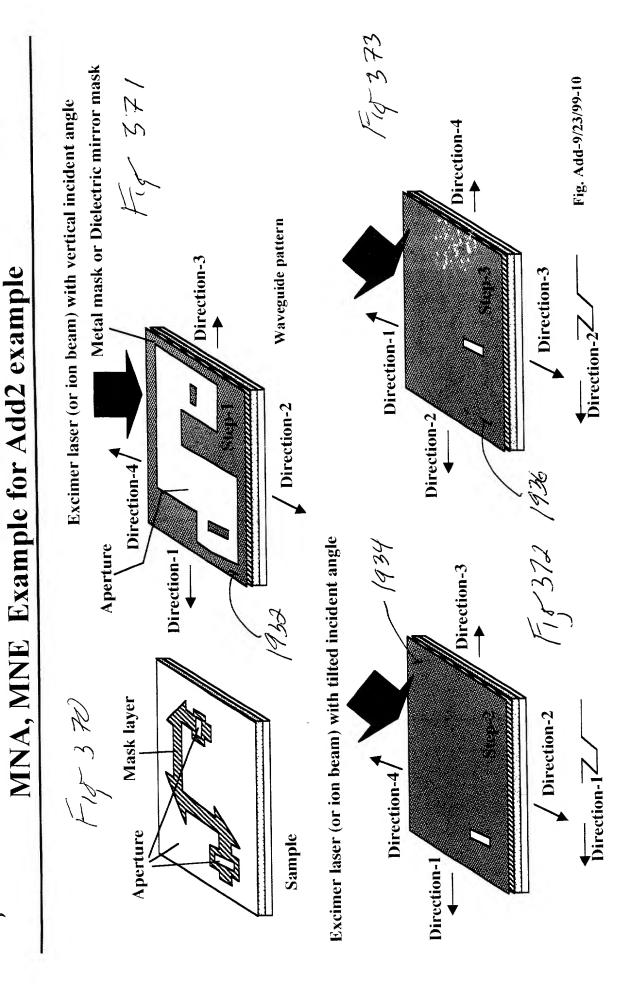


In the case of multi layer (a1-a12) process is repeated on the (a12).



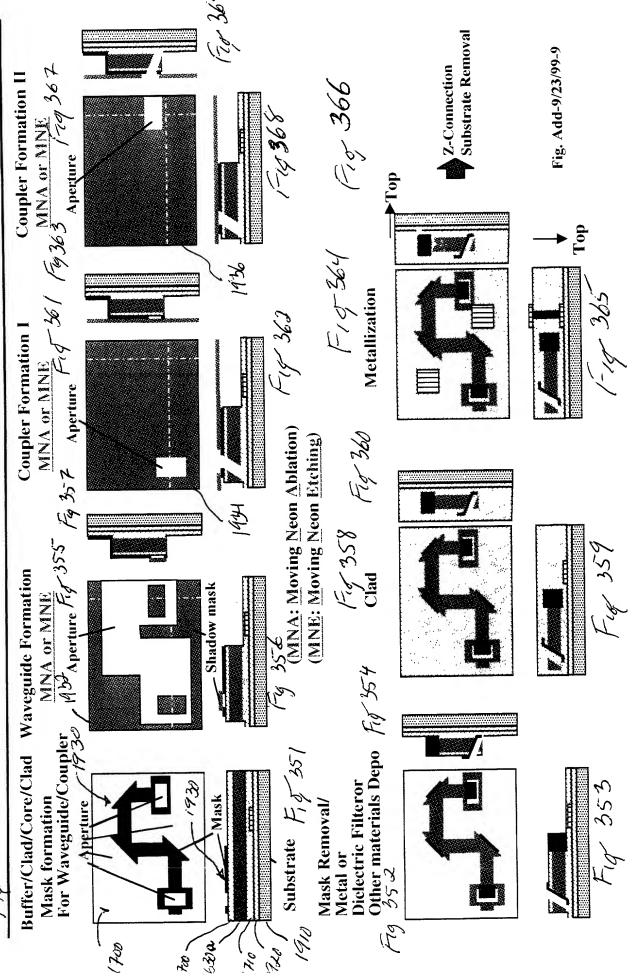
Invented Corner Turning Structure (A)





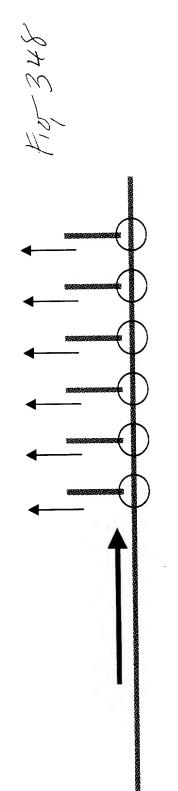
FUITSU Computer Packaging Technologies, Inc.

Another Process Flow for Structure (II) 55 P/4

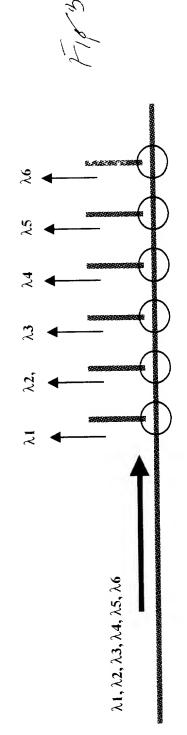


FUJITSU Computer Packaging Technologies, Inc.

Excimer Laser Ablation Example for Beveled Cut (2)



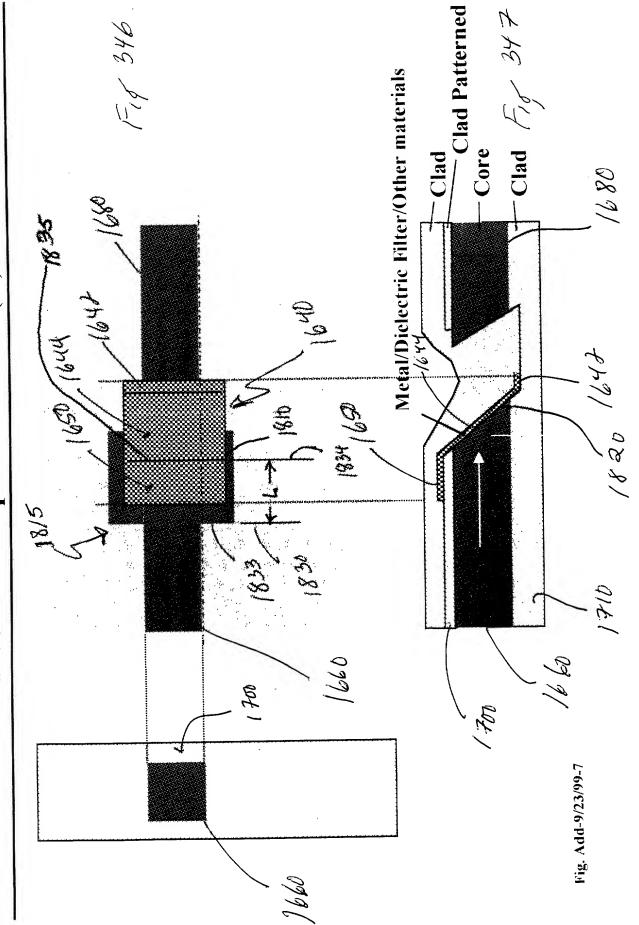
Beam Splitter



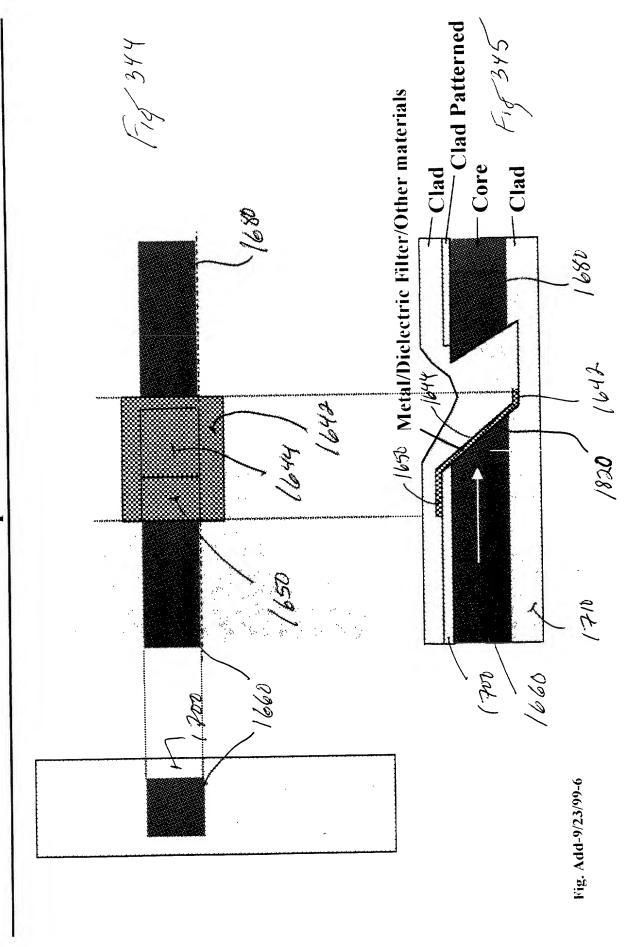
WDM DEMAX

Fig. Add-9/23/99-8

Invented Coupler Structure (II)

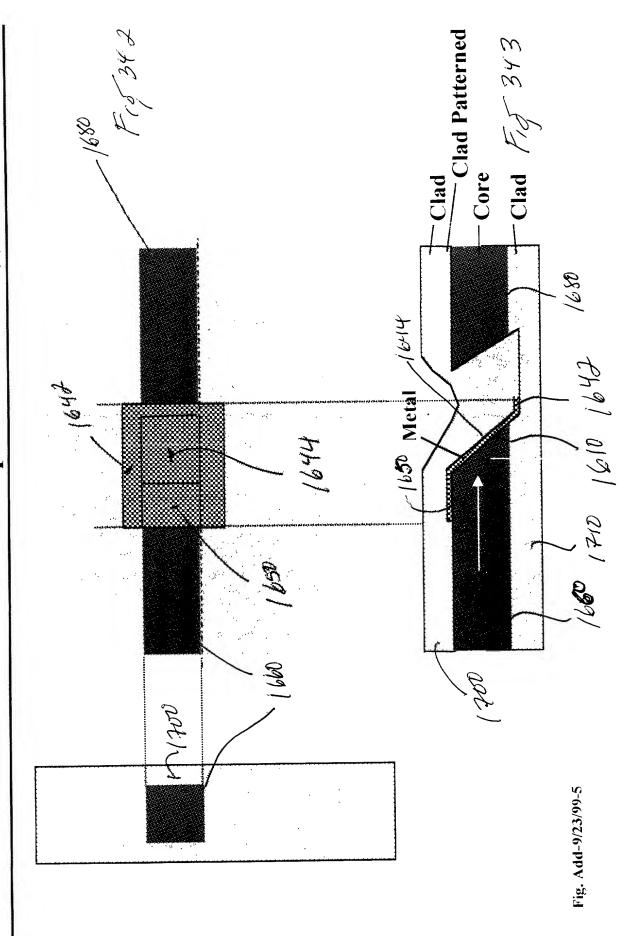


Invented Coupler Structure (I)



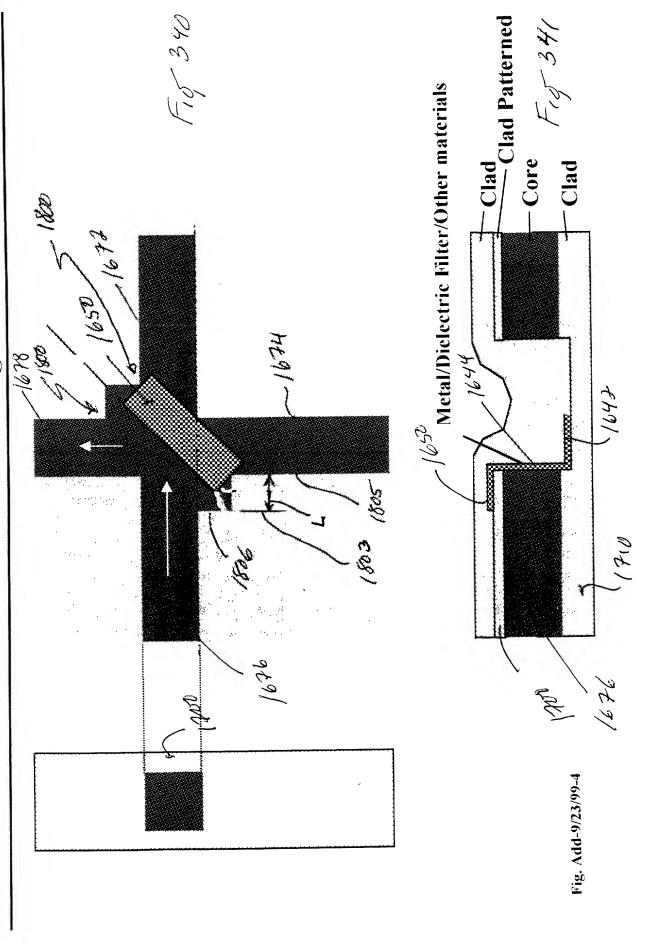
FUJITSU Computer Packaging Technologies, Inc.

Conventional Coupler Structure (I)

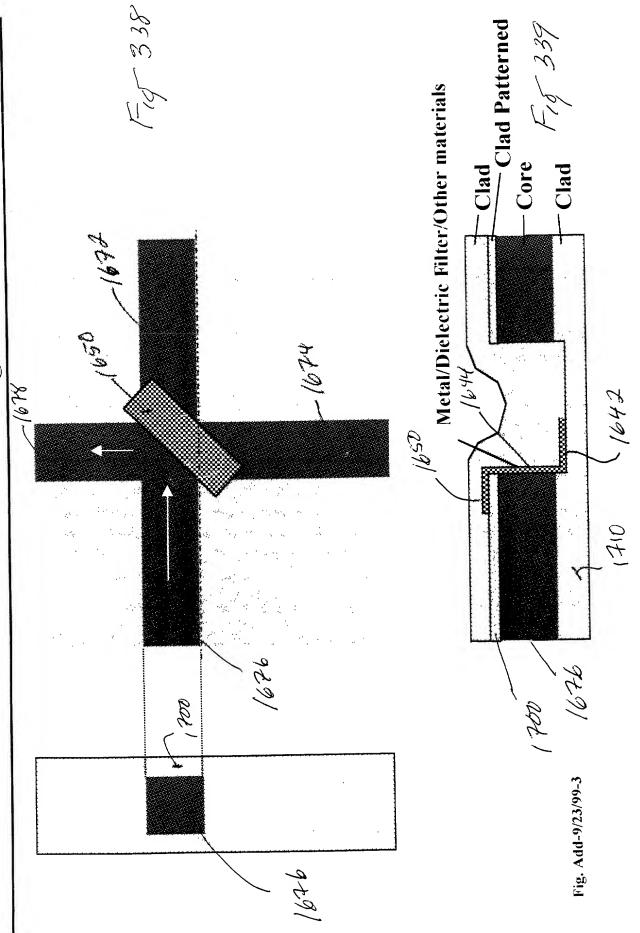


FUJITSU Computer Packaging Technologies, Inc.

Invented Corner Turning Structure (II)

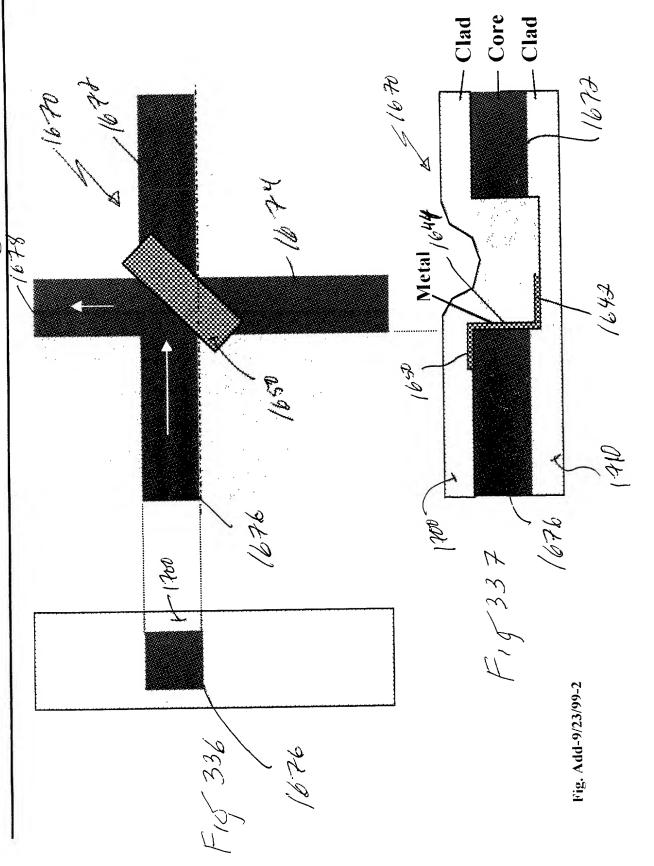


Invented Corner Turning Structure (I)



FUJTSU Computer Packaging Technologies, Inc.

Conventional Corner Turning Structure



Conventional and Invented Waveguide Structure Examples

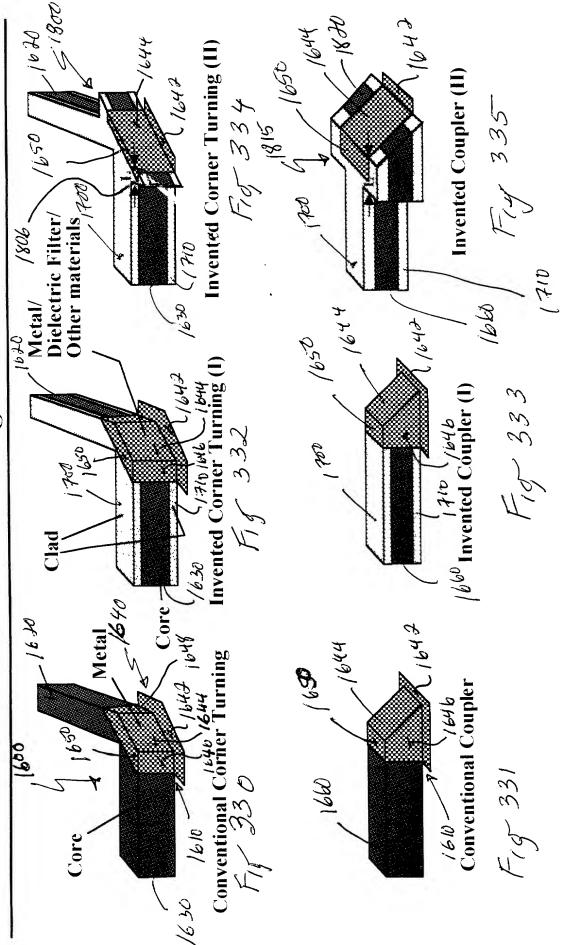
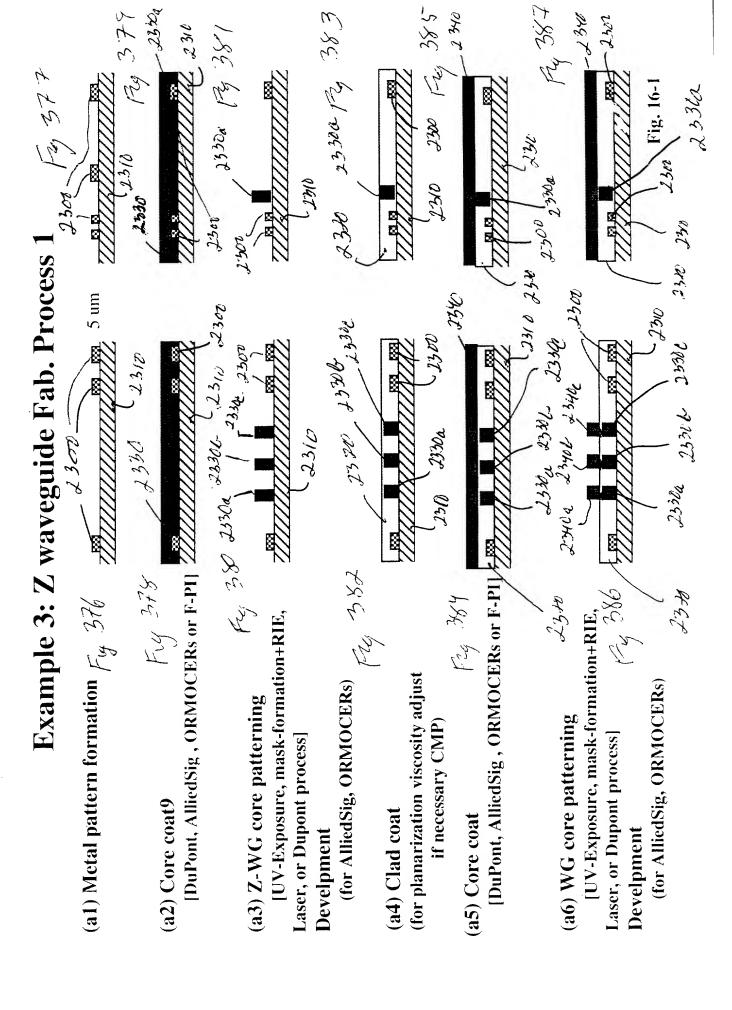


Fig. Add-9/23/99-1



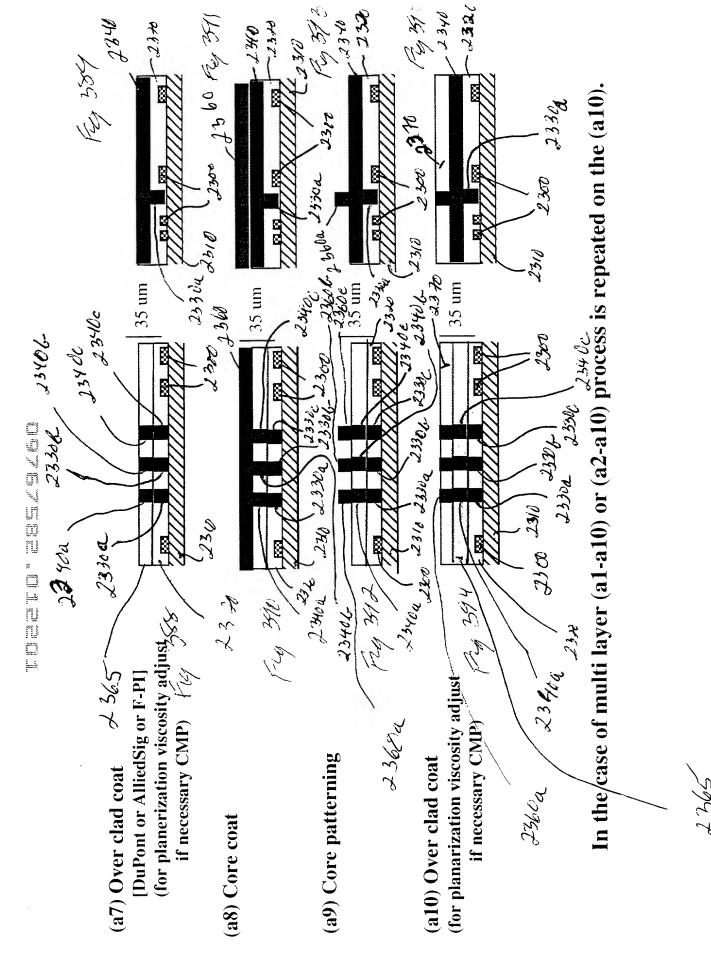
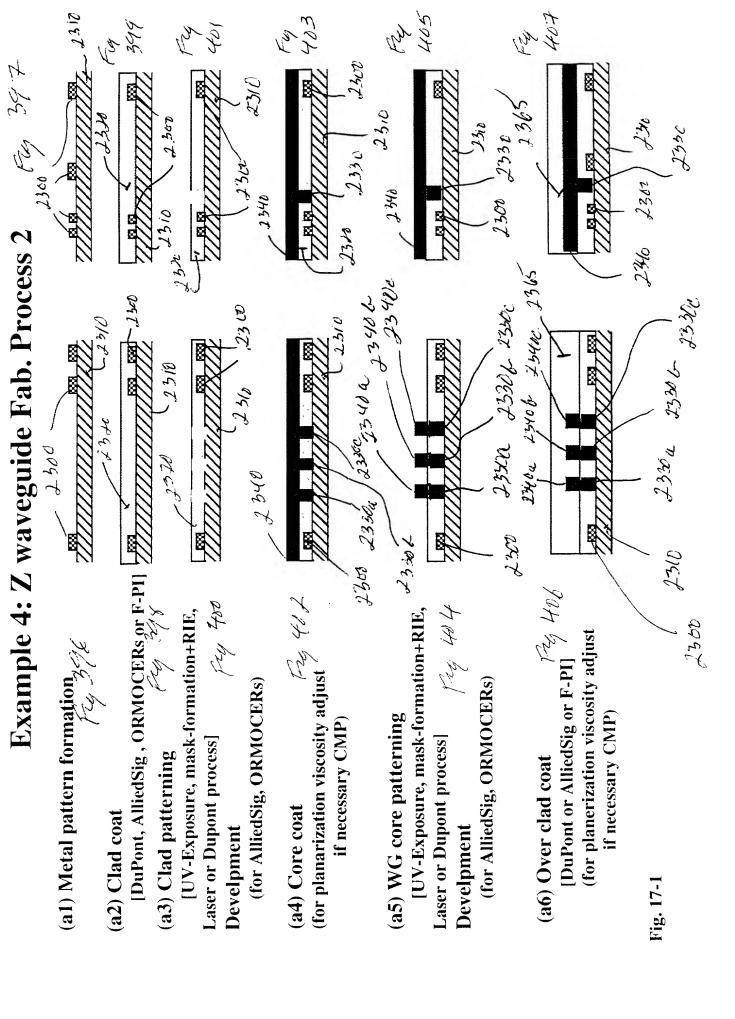
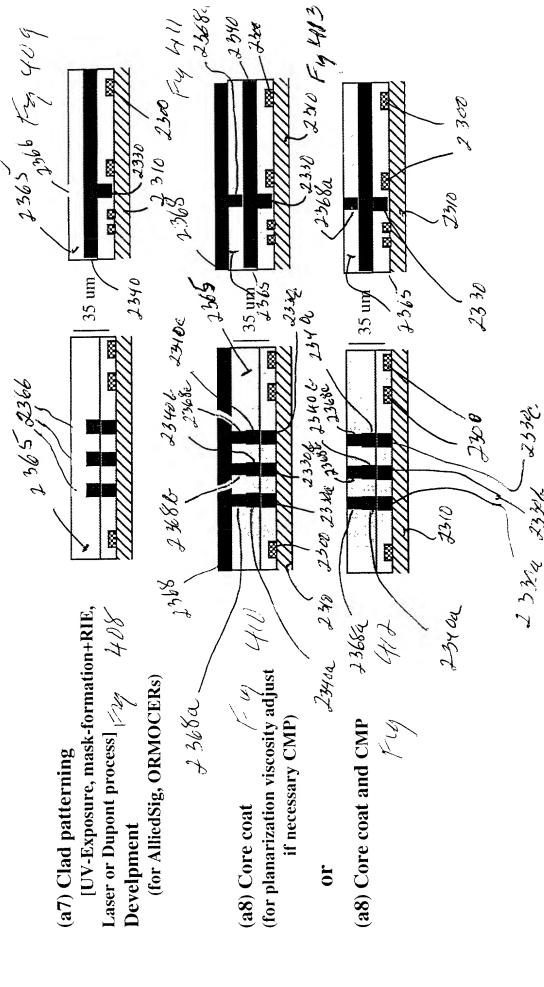
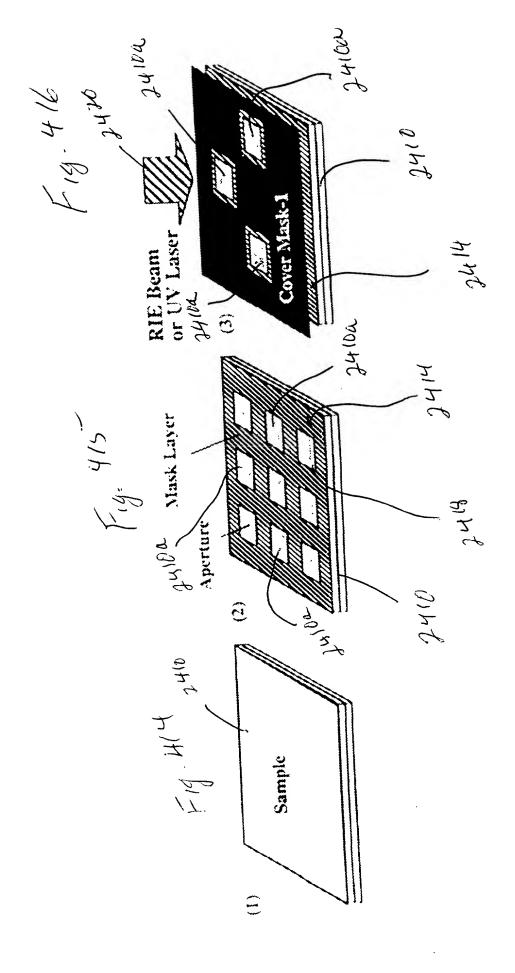


Fig. 16-2





In the case of multi layer (a1, a5-a8) or (a5-a8) process is repeated on the (a8).



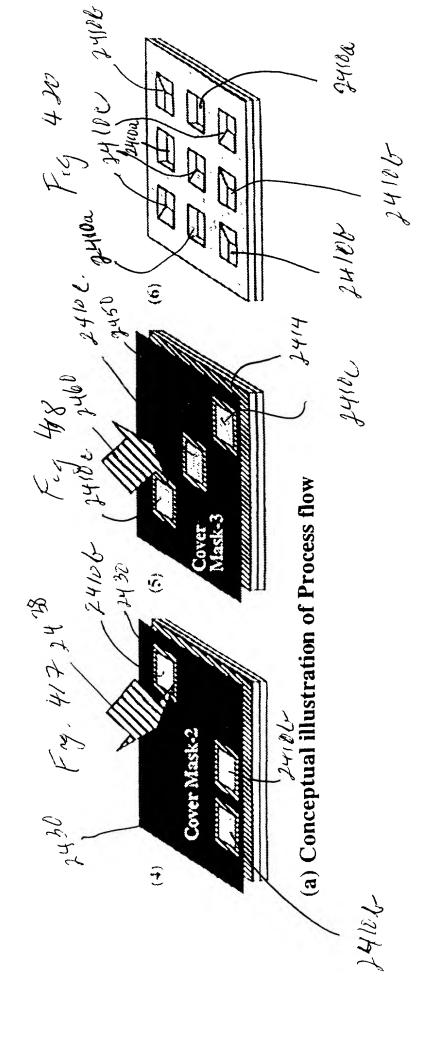
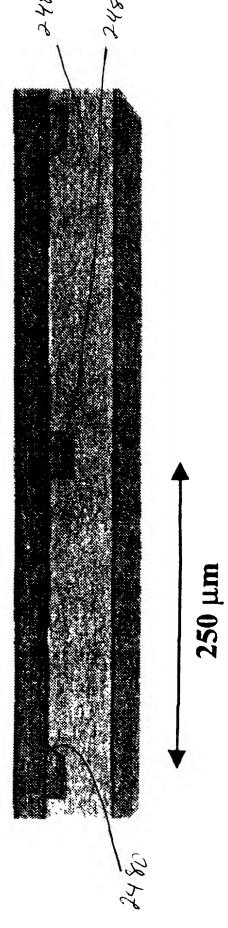


Fig. 421



(b) Trench wall formation of three different angles